



Dr. AMBEDKAR INSTITUTE OF TECHNOLOGY

(An Autonomous Institute affiliated to VTU, Accredited by NAAC with 'A' grade)

BDA Outer Ring Road, Mallathalli, Bengaluru-56

Board Of Studies 2023-24



Approved Scheme and Syllabus of III & IV Semester For 2022 Batch

Submitted by

Department of Electronics and Communication Engineering

> To DEAN (Academic)

					hoice Base nd Commu octive from	ed Credi unication	t System Engine	ering	23-24				
III S	SEMESTE	ER											
		Course		g n ing	Т	eaching	Hours /V	Veek		Ex	aminatio	on	
SI. No	Course	Code	Course Title	Teaching Department (TD) and Question Paper Setting	н Theory Lecture	L Tutorial	ы Practical/ Drawing	Self study	Duration in hours	CIE Marks	SEE Marks	Total Marks	Credits
	DCC	22MAT301xx	Maths for AV Communication				Р 0	3	<u> </u>	<u>じ</u> 50	<u>50</u>	Ē	4
1	BSC			Maths	3	2							4
2	IPCC	22ECU302	Digital System Design using Verilog		3	0	2		03	50	50	100	4
3	IPCC	22 ECU303	Analog Electronic Circuits	ECE	3	0	2		03	50	50	100	4
4	PCC	22ECT304	Network Analysis	ECE	3	0	0		03	50	50	100	3
5	PCCL	22ECL305	Analog and Digital Electronics Laboratory	ECE	0	0	2		03	50	50	100	1
6	ESC	22ECT306x	ESC/ETC/PLC	ECE	3	0	0		03	50	50	100	3
7	UHV	22HST307	Social Connect and Responsibility	Any Department	0	0	2		01	100		100	1
8	AEC/ SEC	22ECT308x or	Ability Enhancement Course/Skill Enhancement	ECE	If the course is a Theory100			01	50	50	100	1	
	SEC	22ECL308x	Course – III	-	If a	course i	s a labor	atory	02				
					0	0	2						
9	HS	22CDN309	Aptitude and Verbal Ability Skill-I	Placement Cell	2	0	0			50		50	PP/NP
		22NSN310	National Service Scheme (NSS)	NSS coordinator	0	0	2			100		100	PP/NP
10	MC	22PEN310	Physical Education (PE) (Sports and Athletics)	Physical Education Director	v		-			100		100	
		22YON310	Yoga	Yoga Teacher									
								r	Fotal	550	350	900	21

PCC: Professional Core Course, **PCCL**: Professional Core Course laboratory, **UHV**: Universal Human Value Course, **MC**: Mandatory Course (Non-credit), **AEC**: Ability Enhancement Course, **SEC**: Skill Enhancement Course, **L**: Lecture, **T**: Tutorial, **P**: Practical, S= Self-Study, **CIE**: Continuous Internal Evaluation, **SEE**:Semester End Evaluation. K: This letter in the course code indicates common to all the streams of Engineering. ESC: Engineering Science Course, ETC: Emerging Technology Course, PLC: Programming Language Course

Engineering Science Course (ESC/ETC/PLC) 22ECT306x										
22ECT306A	Signals and system	22ECT306C	Computer Organization and Architecture							
22ECT306B	Sensors and Instrumentation	22ECT306D	Applied Numerical methods							
	Ability Enhancement Course – II	I 22ECT308x (OR 2ECL308x							
22ECL308A	LICs Lab using PSPICE	22ECL308C	Digital Engineering Course (NASSCOM)							
22ECL308B	Simulink Programming Basics	22ECL308D	IOT for Smart Infrastructure							

Professional Core Course (IPCC): Refers to Professional Core Course Theory Integrated with practical of the same course. Credit for IPCC can be 04 and its Teaching– Learning hours (L : T : P) can be considered as (3 : 0 : 2) or (2 : 2 : 2). The theory part of the IPCC shall be evaluated both by CIE and SEE. The practical part shall be evaluated by only CIE (no SEE). However, questions from the practical part of IPCC shall be included in the SEE question paper.

National Service Scheme /Physical Education/Yoga: All students have to register for any one of the courses namely National Service Scheme (NSS), Physical Education (PE)(Sports and Athletics), and Yoga(YOG) with the concerned coordinator of the course during the first Week of III semesters. Activities shall be carried out between III semester to the VI semester (for 4 semesters). Successful completion of the registered course and requisite CIE score is mandatory for the award of the Degree. The events shall be appropriately scheduled by the colleges and the same shall be reflected in the calendar prepared for the NSS, PE, and Yoga activities. These courses shall not be considered for vertical progression as well as for the calculation of SGPA and CGPA, but completion of the course is mandatory for the award of Degree.

Dr.Ambedkar Institute of Technology, Bengaluru-560056 Outcome Based Education(OBE) and Choice Based Credit System B.E. Name of the programme: Electronics and Communication Engineering

Tentative Scheme of Teaching and Examination effective from the Academic Year 2023-24

(Applicable to 2022 batch)

IV SEMESTER

					Teachir	ng Hou	rs /Weel	κ.	Examina	ation			
SI. Course and Course No Code		and Course	Course Title	Teaching Department (TD) and Question Paper Setting Board (PSB)	T Theo rv	Tu	त्त Practical/ Drawing	& Self - Study	Duration in hours	CIE Marks	SEE Marks	Total Marks	Credits
1	PCC	22ECT401	Engineering Electromagnetics	ECE	3	0	0		03	50	50	100	3
2	IPCC	22ECU402	Principles of Communication Systems	ECE	3	0	2		03	50	50	100	4
3	IPCC	22ECU403	Modern Control systems	ECE	3	0	2		03	50	50	100	4
4	PCCL	22ECL404	Communication laboratory	ECE	0	0	2		03	50	50	100	1
5	ESC	22ECT405x	ESC/ETC/PLC	ECE	3	0	0		03	50	50	100	3
					If the course is Theory				01				
6		22ECT406x	Ability Enhancement Course/Skill	ECE	1	0	0			50	50	100	1
	SEC	or	Enhancement Course- IV		If	the cou	irse is a	lab	02				
		22ECL406x			0	0	2						
7	BSC	22BIT407	Biology For Engineers	TD / PSB: BT, CHE,	2	0	0		03	50	50	100	2
8	UHV	22HST408	Universal human values course	Any Department	1	0	0		01	50	50	100	1
9	HS	22CDN409	Aptitude and Verbal Ability Skill-II	Placement Cell	2	0	0			50		50	PP/ NP
		22NSN410	National Service Scheme (NSS)	NSS coordinator									
10	МС	22PEN410	Physical Education (PE) (Sports and Athletics)	Physical Education Director	0	0	2			100		100	PP/ NP
		22YON410	Yoga	Yoga Teacher									
								T	otal	500	400	900	19

Engineering Science Course (ESC/ETC/PLC) 22ECT405x OR 22ECL405x									
22ECT405A	8051 Microcontroller	22ECT405C	Operating Systems						
22ECT405B	Power Electronics	22ECT405D	Engineering Statistics and Linear Algebra						
	Ability Enhancement Course / Skill Enhancement Course – IV 22XXT405x OR 22XXL406x								
22ECL406A	C++ Basics	22ECL406C	LabVIEW Programming						
22ECL406B	Electronic Devices	22ECL406D	Risk Management in IOT Implementation						
Professional	Core Course (IPCC): Refers to Professional Core Course Theory Integr	ated with practic	cal of the same course. Credit for IPCC can be 04 and its Teaching-						
Learning hour	rs $(L : T : P)$ can be considered as $(3 : 0 : 2)$ or $(2 : 2 : 2)$. The theory pa	rt of the IPCC s	hall be evaluated both by CIE and SEE. The practical part shall be						
evaluated by c	only CIE (no SEE). However, questions from the practical part of IPCC sh	hall be included i	in the SEE question paper.						
National Serv	vice Scheme /Physical Education/Yoga: All students have to register for	any one of the c	courses namely National Service Scheme (NSS), Physical Education						
(PE)(Sports an	nd Athletics), and Yoga(YOG) with the concerned coordinator of the co	urse during the f	first Week of III semesters. Activities shall be carried out between						
III semester to	o the VI semester (for 4 semesters). Successful completion of the register	ered course and	requisite CIE score is mandatory for the award of the Degree. The						
events shall be	e appropriately scheduled by the colleges and the same shall be reflected if	in the calendar p	repared for the NSS, PE, and Yoga activities. These courses shall						
not be conside	ered for vertical progression as well as for the calculation of SGPA and C	CGPA, but comp	letion of the courses is mandatory for the award of Degree.						

Assessment and Evaluation method

III Semester:

- 22ECU302- Digital System Design using Verilog shall have the 03 hours of theory examination (SEE), however, practical sessions question shall be included in the theory question papers
- **22ECU303- Analog Electronic Circuits** shall have the 03 hours of theory examination), however, practical sessions question shall be included in the theory question papers.
- ESC or ETC, of 03 credits Courses shall have only a theory component (L: T :P:S=3:0:0:0) or if the nature the of course required practical learning then the syllabus shall be designed as an Integrated course (L: T:P:S= 2:0:2:0). All PLC courses are Integrated courses.
- All 01 Credit courses shall have the SEE of 02 hours duration and the pattern of the question paper shall be MCQ
- Integrated courses (IPCC) will have 50 marks CIE and 50 Marks SEE.
- Non-integrated courses (PCC) have 50 marks CIE (including 5 marks Assignment and 5 marks Group Activity) and 50 Marks SEE.

IV Semester:

- **22ECU402- Principles of Communication Systems** shall have the 03 hours of theory examination (SEE), however, practical sessions question shall be included in the theory question papers
- **22ECU403-** Modern Control systems shall have the 03 hours of theory examination), however, practical sessions question shall be included in the theory question papers.
- ESC or ETC, of 03 credits Courses shall have only a theory component (L: T :P:S=3:0:0:0) or if the nature the of course required practical learning then the syllabus shall be designed as an Integrated course (L: T:P:S= 2:0:2:0). All PLC courses are Integrated courses.
- All 01 Credit- courses shall have the SEE of 02 hours duration and the pattern of the question paper shall be MCQ
- Integrated courses (IPCC) will have 50 marks CIE and 50 Marks SEE.
- Non-integrated courses (PCC) have 50 marks CIE (including 5 marks Assignment and 5 marks Group Activity) and 50 Marks SEE.

DIGI	TAL SYSTI	EM DESIGN USIN	NG VERILOG						
Course Code:		22ECU302	CIE Marks:	50					
Teaching Hours/Week (L:T:P	P:S):	04	SEE Marks:	50					
Total Hours of Pedagogy:52Total Marks:100									
Credits:		04	Exam Hours:	03					
Course objectives:									
1. To impart the concepts	of simplifyii	ng Boolean express	ion using K-map techniqu	les and Quine-					
McCluskey minimizatio	on technique	s.							
2. To impart the concepts of	of designing	and analyzing com	binational logic circuits.						
3. To impart design metho	ds and analy	sis of sequential log	gic circuits.						
1 0	•	1 .	d behavioural models for	the design of					
digital systems.	C			U					
		Module-1							
Principles of Combination	nal Logic:		mbinational logic. Cano	onical forms.					
Generation of switching equa	e		0						
McCluskey Minimization Tec			• • •						
(Section 3.1 to 3.5 of Text 1).	Xun								
Teaching Learning Method:	Challs and		202						
RBT Level:		Talk, YouTube vid	eos						
	L1, L2, L3								
		Module-2							
Logic Design with MSI Con	-	8	e	•					
Subtractors, Comparators, Dec	coders, Enco	ders, Multiplexers,	, Programmable Logic De	evices (PLDs)					
(Section 5.1 to 5.7 of Text 2)	1								
Teaching Learning Method:		Talk, YouTube vid	eos						
RBT Level:	L1, L2, L3								
		Module-3							
Flip-Flops and its Application	tions: The	Master-Slave Flip	-flops (Pulse-Triggered fl	ip-flops): SR					
flip-flops, JK flip flops, Chara	acteristic equ	ations, Registers,	Binary Ripple Counters,	Synchronous					
Binary Counters, Counters bas	sed on Shift	Registers, Design	of Synchronous mod-n C	Counter using					
clocked T, JK, D and SR flip-fl	lops. (Sectio	on 6.4, 6.6 to 6.9 (Ex	cluding 6.9.3) of Text 2)						
Teaching Learning Method:	Chalk and	l Talk, YouTube vi	deos						
RBT Level:	L1, L2, L2								
	L_1, L_2, L_3	Module-4							
Introduction to Verilog:	Typical D		types, Modules, Ports.						
Verilog Data flow descript	• •	-	• -	Derators and					
operands, operator types, Exam		-	• •	permise, and					
Teaching Learning Method:	-								
RBT Level:			eos, Programming assign	iments					
	L1, L2, L3								
		Module-5							

Verilog Behavioral description	Procedural Assignmen	ts, Conditional	statements,	Multiway
branching, Loops, Examples. (Sect	on 7.2, 7.4, 7.5, 7.6 and 7	7.9 of Text 3)		
Verilog Structural description:	Gate types, Examples	. (Section 5,1	of Text 3)	(Gate level
description only)				
Teaching Learning Methods				

Teaching Learning Method:	Chalk and Talk, YouTube videos, Programming assignments
	L1, L2, L3

PRACTICAL COMPONENT OF IPCC

Using suitable simulation software, demonstrate the operation of the following circuits

Sl. No.	Experiments								
1	To simplify the given Boolean expressions and realize using Verilog program.								
2	To realize Adder/Subtractor (Full/half) circuits using Verilog data flow description.								
3	To realize 4-bit ALU using Verilog program.								
4	To realize the following Code converters using Verilog Behavioral description								
	a) a) Gray to binary and vice versa b) Binary to excess3 and vice versa								
5	To realize using Verilog Behavioral description: 8:1 mux, 8:3 encoder, Priority encoder								
6	To realize using Verilog Behavioral description: 1:8 Demux, 3:8 decoder, 2-bit Comparator								
7	To realize using Verilog Behavioral description:								
	Flip-flops: a) JK type b) SR type c) T type and d) D type								
8	To realize Counters - up/down (BCD and binary) using Verilog Behavioral description.								
	Demonstration Experiments (For CIE only – not to be included for SEE)								
Use FPGA	A/CPLD kits for downloading Verilog codes and check the output for interfacing experiments.								
9	Verilog Program to interface a Stepper motor to the FPGA/CPLD and rotate the motor in								
	thespecified direction (by N steps).								
10	Verilog programs to interface a Relay or ADC to the FPGA/CPLD and demonstrate its								
	working.								

11 Verilog programs to interface DAC to the FPGA/CPLD for Waveform generation.

12	Verilog programs to interface Switches and LEDs to the FPGA/CPLD and demonstrate its
	working.

Course Outcomes

At the end of the course the student will be able to:

- 1. Simplify Boolean functions using K-map and Quine-McCluskey minimization technique.
- 2. Analyze and design for combinational logic circuits.
- 3. Analyze the concepts of Flip Flops (SR, D, T and JK) and to design the synchronous sequential using Flip Flops.
- 4. Model Combinational circuits (adders, subtractors, multiplexers) and sequential circuits using Data flow model.
- 5. Model Combinational circuits (multiplexers) and sequential circuits using behavioural and structural model.

Suggested Learning Resources:

Text Books

1. Digital Logic Applications and Design by John M Yarbrough, Thomson Learning, 2001.

2. Digital Principles and Design by Donald D Givone, McGraw Hill, 2002.

3. HDL Programming VHDL and Verilog by Nazeih M Botros, 2009 reprint, Dream tech press.

Reference Books:

1. Fundamentals of logic design, by Charles H Roth Jr., Cengage Learning

2. Logic Design, by Sudhakar Samuel, Pearson/Sanguine, 2007

3. Fundamentals of HDL, by Cyril P R, Pearson/Sanguine2010

MOOCS:

- 1. Electronic Design Automation <u>http://nptel.ac.in/courses/106105083/</u>
- 2. Digital system design with PLDs and FPGA shttp://nptel.ac.in/courses/117108040/Fundamentals of HDL

Activity Based Learning (Suggested Activities in Class)/Practical Based learning

Programming Assignments/Mini Projects can be given to improve programming skills.

							CO-I	20 Ma	appınş	5					
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	3	1	1											2	
CO2	3	1	1											2	
CO3	3	1	1											2	
CO4	3	1	1											2	
CO5	3	1	1											2	
High-	ligh-3, Medium-2, Low-1														

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	ANALOG ELECTRON	C CIRCUITS	
Course Code:	22ECU303	CIE Marks:	50
Teaching Hours/Week (L:T:P	:S): 3:0:2:0	SEE Marks:	50
Total Hours of Pedagogy:	52	Total Marks:	100
Credits:	Exam Hours:	3	
Course objectives: This cours	e will enable students to		
1. Explain various BJT paramet	ters, connections and config	gurations.	
2. Design and demonstrate the	diode circuits and transistor	amplifiers.	
3. Explain various types of FET	biasing and demonstrate the	ne use of FET amplifiers.	
4. Analyse Power amplifier circ	cuits in different modes of c	peration.	
5. Construct Feedback and Osc		1	
	Module-1		08 hrs
BJT Biasing: Biasing in BJT a	-	ical Discrete circuit bias (Vol	tage-divider bias),
Biasing using a collector to bas	e feedback resistor.		
Small signal operation and N	Models: Collector current	and transconductance, Base	current and input
resistance, Emitter current and	input resistance, voltage ga	in, Separating the signal and	the DC quantities,
The hybrid Π model.			
MOSFETs : Biasing in MOS an	nplifier circuits: Fixing VG	S, Fixing VG, Drain to Gate	feedback resistor.
Small signal operation and mod	eling: The DC bias point, si	gnal current in drain, voltage	gain, small signal
equivalent circuit models, trans			
Teaching Learning Method:	Chalk and talk method, Po	ower Point Presentation.	
8 8		JT Amplifier Configurations-	- Design of
		nmon collector amplifier circ	
RBT Level:	L1, L2, L3		
	Module-2		08 hrs
MOSFET Amplifier configur		s, characterizing amplifiers,	CS amplifier with
and without source resistance R	S, Source follower.		
MOSFET internal capacitan	ces and High frequency	model: The gate capacitiv	e effect, Junction
capacitances, High frequency m	odel. Frequency response of	of the CS amplifier: The three	e frequency bands,
high frequency response, Low t	frequency response.		
Oscillators: FET based Phase s	shift oscillator, LC and Crys	stal Oscillators (no derivation	a) Text 1
Teaching Learning Method:	Chalk and talk method, Po	ower Point Presentation.	
8 8	Self-study topics: Discrete	e Circuit MOS Amplifier – Tl	ne common
	source amplifier and the s	ource follower.	
RBT Level:	L1, L2, L3		_
	Module-3		08 hrs
Feedback Amplifier: General	· .	e -	
Feedback Topologies, The serie	es-shunt, series-series, shun	t-shunt and shunt-series amp	lifiers (Qualitative
Analysis).			
Output Stages and Power Am	plifiers: Introduction, Class	sification of output stages, Cl	ass A output stage,
Class B output stage: Transfer (Characteristics, Power Dissi	pation, Power Conversion ef	ficiency, Class AB

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output stage, Class C tuned Amplifier. Text 1

Teaching Learning Method:	Chalk and talk method, Power Point Presentation.	
	Self-study topics: Class D power amplifier	
RBT Level:	L1, L2, L3	
	Module-4	08 hrs
Op-Amp Circuits: Op-amp D	C and AC Amplifiers, DAC – Weighted resistor and R-	-2R ladder, ADC-
Successive approximation type	, Small Signal half wave rectifier, Absolute value output	circuit,
Active Filters, First and second	l order low-pass and high-pass Butterworth filters, Band-	pass filters, Band
reject filters. (no derivations on	ly concepts) Text 2	
Teaching Learning Method:	Chalk and talk method, Power Point Presentation.	
	Self-study topics: Clippers and Clampers, Peak detector	r, Sample and
	hold circuit.	
RBT Level:	L1, L2, L3	
	Module-5	08 hrs
	s: Monostable and Astable Multivibrators.	
	node characteristics and Gate characteristics of SCR, T	
	f Methods: Natural and Forced Commutation - Class	A without design
consideration. Text 2, 3		
Teaching Learning Method:	Chalk and talk method, Power Point Presentation.	1 0
	Self-study topics: Basic Construction, working and app	lications of
RBT Level:	DIAC, TRIAC, IGBT, GTO. L1, L2, L3	
KDI Level:	PRACTICAL COMPONENT OF IPCC	
1. Design and verification using OP-AMP.	of voltage follower, inverting amplifier and non- invertin	ng amplifier
2. Design and verification	of Integrator and Differentiator using OP-AMP.	
generator using OP-AN		ular wave
* * *	characteristics of BJT Common emitter	
	of input and output characteristics of MOSFET	
6. Analyze of Static chara		
	of RC Phase shift Oscillator using FET.	
8. Design and Simulation Course Outcomes:	of K-2R Ladder DAC.	
After the completion of the C	Sourse the student can:	
-	istics of BJTs and FETs for switching and amplifier circu	lite
	amplifiers and oscillators with different circuit configura	
and biasing conditions.	amplifiers and oscillators with different circuit configura	uons
e	topologies and approximations in the design of amplifier	•0
and oscillators.	topologies and approximations in the design of amplifier	.5
	inear ICs for wide range applications such as ADC, DAC	filters and
timers.	mearies for while range applications such as ADC, DAC	, muis anu
	DC .	
Suggested Learning Resource	-5.	
	s, Theory and Applications, Adel S Sedra, Kenneth C S	mith, 6 th Edition,
Oxford,2015. ISBN:978	5-0-19-808913-1	

- 2. Op-Amps and Linear Integrated Circuits, Ramakant A Gayakwad, 4th Edition, Pearson Education, 2018. ISBN: 978-93-325-4991-3
- 3. Electronic Principles, Albert Malvino, David J Bates, 7th Edition, McGraw Hill Education
- 4. (India)Private Limited, 2017, ISBN:978-0-07-063424-4Reference Books (if required)

Web Links:

- 1. <u>www.nptel.in</u>
- 2. Integrated Electronics: Analog and Digital Circuits and Systems, Jacob Millman, Christos
- 3. C.Halkias, McGraw-Hill, 2015.
- 4. Electronic Devices and Circuit, Boylestad & Nashelsky, Eleventh Edition, Pearson, January 2015.

CO-PO Mapping

	P01	P02	PO3	P04	P05	P06	P07	P08	P09	P010	P011	P012	PSO1	PSO2	PSO3
CO1	3	3											1	1	1
CO2	3	3	3										1	1	1
CO3	3	3	2										1	1	1
CO4	3	2	2										1	1	1
High-3	, Medi	um-2,	Low-1												

	NETWORK ANALYSIS		
Course Code:	22ECT304 CIF	Marks:	50
Teaching Hours/Week (L:T:P:S):	2:2:0:0 SEI	E Marks:	50
Total Hours of Pedagogy:	52 Hours Tota	al Marks:	100
Credits:	3 (2:1:0) Exa	m Hours:	03 Hrs
Course objectives:			
1. To familiarize the basic laws, source	e transformation, source shifting and n	etwork analysis	techniques.
2. To understand the network theorems		•	-
3. To understand the transient behavio			
4. To Apply Laplace transforms for the	analysis of electrical circuits.		
5. To evaluate the two port network pa	•		
_	Module-1		11 hrs
Introduction: Ohm's Law, Nodes, Bra	unches, and Loops, Kirchhoff's Laws,	Series Resistors	and Voltage
division, Parallel Resistors and Curre	ent division, Wye-Delta transformation	ons, Source Tra	nsformation,
Source Shifting, Series and Parallel Ca	-		,
Methods of Analysis: Nodal Analysis	is, Nodal Analysis with Voltage Sou	rces, Mesh Ana	alysis, Mesh
Analysis with Current Sources, Noda			•
Analysis and Mesh Analysis.		-	C
Text Book: 2.1 to 2.7, 4.4, 6.3, 6.5, 3.	1 to 3.7, 10.1 to 10.3.		
Teaching Learning Method:	Chalk and Board, Problem Based Lea	urning	
RBT Level:	L1, L2, L3, L4	C	
	Module-2		10 hrs
Circuit Theorems: Linearity Prop	erty, Superposition, Thevenin's The	eorem, Norton ²	s Theorem,
Maximum Power Transfer theorem.			
Resonance: Series resonance and para	llel resonance		
Text Book: 4.2,4.3, 4.5, 4.6, 10.4, 10.4	5, 14.5, 14.6.		
Teaching Learning Method:	Chalk and Board, Problem Based Lea	urning	
Teaching Learning Method: RBT Level:	Chalk and Board, Problem Based Lea L1, L2, L3, L4	urning	
0	Chalk and Board, Problem Based Lea L1, L2, L3, L4 Module-3	urning	11 hrs
RBT Level:	L1, L2, L3, L4 Module-3		
RBT Level: Transient Behaviour and Initial Cor	L1, L2, L3, L4 Module-3 ditions: Introduction, the Source-Free	e RC circuit, the	Source-
RBT Level: Transient Behaviour and Initial Cor Free RL circuit, Singularity Functions	L1, L2, L3, L4 Module-3 ditions: Introduction, the Source-Free	e RC circuit, the	Source-
RBT Level: Transient Behaviour and Initial Cor Free RL circuit, Singularity Functions Finding Initial and Final Values.	L1, L2, L3, L4 Module-3 ditions: Introduction, the Source-Free	e RC circuit, the	Source-
RBT Level: Transient Behaviour and Initial Cor Free RL circuit, Singularity Functions Finding Initial and Final Values. Text Book: 7.1 to 7.6, 8.1, 8.2	L1, L2, L3, L4 Module-3 ditions: Introduction, the Source-Free Step Response of an RC circuit, Step	e RC circuit, the Response of an	Source-
RBT Level: Transient Behaviour and Initial Cor Free RL circuit, Singularity Functions Finding Initial and Final Values. Text Book: 7.1 to 7.6, 8.1, 8.2 Teaching Learning Method:	L1, L2, L3, L4 Module-3 ditions: Introduction, the Source-Free Step Response of an RC circuit, Step Chalk and Board, Problem Based Lea	e RC circuit, the Response of an	Source-
RBT Level: Transient Behaviour and Initial Cor Free RL circuit, Singularity Functions Finding Initial and Final Values. Text Book: 7.1 to 7.6, 8.1, 8.2 Teaching Learning Method:	L1, L2, L3, L4 Module-3 ditions: Introduction, the Source-Free Step Response of an RC circuit, Step	e RC circuit, the Response of an	Source-
RBT Level: Transient Behaviour and Initial Cor Free RL circuit, Singularity Functions Finding Initial and Final Values. Text Book: 7.1 to 7.6, 8.1, 8.2 Teaching Learning Method: RBT Level:	L1, L2, L3, L4 Module-3 Iditions: Introduction, the Source-Free Step Response of an RC circuit, Step Chalk and Board, Problem Based Lea L1, L2, L3, L4 Module-4	e RC circuit, the Response of an urning	Source- RL Circuit, 10 hrs
RBT Level: Transient Behaviour and Initial Cor Free RL circuit, Singularity Functions Finding Initial and Final Values. Text Book: 7.1 to 7.6, 8.1, 8.2 Teaching Learning Method: RBT Level: Laplace Transforms : Introduction,	L1, L2, L3, L4 Module-3 ditions: Introduction, the Source-Free Step Response of an RC circuit, Step Chalk and Board, Problem Based Lea L1, L2, L3, L4 Module-4 Definition of the Laplace Transfo	e RC circuit, the Response of an urning rm, Properties	Source- RL Circuit, 10 hrs
RBT Level: Transient Behaviour and Initial Cor Free RL circuit, Singularity Functions Finding Initial and Final Values. Text Book: 7.1 to 7.6, 8.1, 8.2 Teaching Learning Method: RBT Level: Laplace Transforms : Introduction, Transform, Circuit Element Models, a	L1, L2, L3, L4 Module-3 ditions: Introduction, the Source-Free Step Response of an RC circuit, Step Chalk and Board, Problem Based Lea L1, L2, L3, L4 Module-4 Definition of the Laplace Transfo	e RC circuit, the Response of an urning rm, Properties	Source- RL Circuit, 10 hrs
RBT Level: Transient Behaviour and Initial Cor	L1, L2, L3, L4 Module-3 ditions: Introduction, the Source-Free Step Response of an RC circuit, Step Chalk and Board, Problem Based Lea L1, L2, L3, L4 Module-4 Definition of the Laplace Transfo	e RC circuit, the Response of an urning rm, Properties nsforms.	Source- RL Circuit, 10 hrs

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aching	g Lear	ning	Meth	od:		Chal	k and	Board	d, Pro	blem B	lased L	earnin	g		
BT Lev	vel:					L1, I	L2, L3	3, L4							
ourse o	utcor	nes:													
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cuits.															
D3. Ev				-	-				uits us	sing ini	tial co	ndition	s.		
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	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	3	3											3		
CO2	3	3											3		
CO3	3	3											3		
CO4	3	3											3		
-		-													
CO5	2	2											3		

	ANALOG	AND DIGITAL ELI	ECTRONICS LAB	
Course	e Code:	22ECL305	CIE Marks:	50
Teachi	ng Hours/Week (L:T:P:S):	0:0:2:0	SEE Marks:	50
	Hours of Pedagogy:		Total Marks:	100
Credit	s:	01	Exam Hours:	03
Course	e objectives:			
This la	boratory course enables studer	t to:		
1.	Understand the electronic circ	uit schematic and its v	vorking	
2.	Realize and test amplifier and	oscillator circuits for	the given specifications	
3.	Realize the opamp circuits for	the applications such	as DAC, implement mathe	ematical functions
4.	and precision rectifiers.		-	
5.	Study the static characteristics	of SCR and test the F	C triggering circuit.	
	Design and test the combinati			onalities.
7.	• Use the suitable ICs based o	-		
S1.		Experiments		
No.		Experiments		
1	Design and set up the BJT c	ommon emitter voltag	e amplifier and	
	determine the gain, bandwid	th, input and output in	npedances.	
2	Design and set-up BJT/FET			
	-	or ii) Crystal Oscillat	or	
3	Design and set up the circuit			
		egrator iii) Differen		
4	Obtain the static characterist	tics of SCR and test SO	CR Controlled HWR and F	WR using RC
	triggering circuit.			
5	Design and implement			
5	(a) Half Adder & Full Adder(b) Half subtractor & Full su	5 5	atas	
	(c) 4-variable function using		ales	
6	Realize	, ie / 110 1 (0.11010/1).		
Ŭ	(i) Binary to Gray code conv	version & vice-versa u	using gates	
7	a) Realize using NAND Gat			
	i) Master-Slave JK Flip-Flop		ii) T Flip-Flop	
8	Realize			
	a) Design Mod – N Synchro		own Counter using 7476 J	K Flip-flop
	b) Mod-N Counter using IC			
9	Design 4-bit R – 2R Op-Am		onverter	
	(i) for a 4-bit binary input us	0 00		
10	(ii) by generating digital inp		vorre martifica ::) E-11	naatifian
10	Test the precision rectifiers			recurrer
11	Design and test Monostable	and Astable Multivibr	ator using 555 Timer	

Course outcomes (Course Skill Set):

At the end of the course the student will be able to:

CO 1. Design and analyze the BJT/FET amplifier and oscillator circuits.

CO 2. Design and test Opamp circuits to realize the mathematical computations, DAC and precision rectifiers.

CO 3. Design and test the combinational logic circuits for the given specifications.

CO 4. Test the sequential logic circuits for the given functionality.

CO 5. Demonstrate the basic electronic circuit experiments using SCR and 555 timer.

Suggested Learning Resources:

1. Fundamentals of Electronic Devices and Circuits Lab Manual, David A Bell, 5th Edition, 2009, Oxford University Press.

2. Op-Amps and Linear Integrated Circuits, Ramakant A Gayakwad, 4th Edition, Pearson Education, 2018. ISBN: 978-93-325-4991-3.

3. Fundamentals of Logic Design, Charles H Roth Jr., Larry L Kinney, Cengage Learning, 7th Edition.

	P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PS01	PSO2	PSO3
CO1	3	3	3										1	1	1
CO2	3	3	3										1	1	1
CO3	3	3	3										1	1	1
CO4	3	3	3										1	1	1
CO5	3	3	3										1	1	1
High-3	, Medi	um-2,	Low-1												

CO-PO Mapping

	SIGNALS AND SY	STEM	
Course Code:	22ECT306A	CIE Marks:	50
Teaching Hours/Week (L:T:P:S	5): 3:0:0:0	SEE Marks:	50
Total Hours of Pedagogy:	40	Total Marks:	100
Credits:	03	Exam Hours:	3
Course objectives:			
1. To prepare students with fundation	-		
2. Apply convolution to analyse	how signals interact with	a linear time-invariant (LTI)	systems and the
analysis of the signals in time dom	nain using difference/diffe	crential equations.	
3. Understand the basic concepts	of the Fourier series and H	Fourier transform for a given	signal.
4. Analyse and apply the concepts	s of the Fourier Transform	and its properties.	
5. Understand the concept of the	Z-transform and its signifi	cance in discrete-time signal	analysis.
	Module-1		08 Hrs
Introduction: Definition of sign	nal and systems, classific	ation of signals, basic oper	ations on signals
(Amplitude scaling, addition, m	ultiplication, time scaling	g, time shift and time reve	rsal), Elementary
signals/Functions (Unit Step, Uni	t impulse, ramp, exponent	ial, sinusoidal).	
Properties of System: Linear-no	nlinear, Time variant-inva	riant, causal-noncausal, men	nory-memoryless,
stable-unstable.			• •
Teaching Learning Method:	Chalk and Talk, power p	oint presentation, animations,	videos
RBT Level:	L1, L2	1	
	Module-2		08 Hrs
Time domain representations for		Svstems:	
Introduction, Convolution: Impu		-	es of the impulse
response representation for LTI			_
systems.	<i>zjzzzzzzzzzzzzz</i>		
Teaching Learning Method:	Chalk and Talk power po	oint presentation, animations	videos
RBT Level:	L1, L2, L3, L4		, 110005
	Module_3		08 Hrs
Fourier representations of sign	Module-3		08 Hrs
Fourier representations of signa	als:	Time Fourier Series Continue	
Introduction, Discrete-Time Perio	als: dic signals: The Discrete-7		ous-Time Periodic
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc	als: dic signals: The Discrete- crete-Time Non Periodic s	ignals: The Discrete-Time F	ous-Time Periodic ourier Transform,
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc Continuous-Time Non Periodic S	als: odic signals: The Discrete- crete-Time Non Periodic s ignals: The Fourier Transf	ignals: The Discrete-Time F form. (Definition and basic pr	ous-Time Periodic ourier Transform, roblems)
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc Continuous-Time Non Periodic S Teaching Learning Method:	als: odic signals: The Discrete- crete-Time Non Periodic s ignals: The Fourier Transf Chalk and Talk, power po	ignals: The Discrete-Time F	ous-Time Periodic ourier Transform, roblems)
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc Continuous-Time Non Periodic S	als: odic signals: The Discrete- crete-Time Non Periodic s ignals: The Fourier Transf Chalk and Talk, power po L1, L2, L3, L4	ignals: The Discrete-Time F form. (Definition and basic pr	ous-Time Periodic ourier Transform, roblems) , videos
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc Continuous-Time Non Periodic S Teaching Learning Method: RBT Level:	als: odic signals: The Discrete-Terete-Time Non Periodic s ignals: The Fourier Transf Chalk and Talk, power per L1, L2, L3, L4 Module-4	ignals: The Discrete-Time F form. (Definition and basic proposed provided and basic proposed provided and basic provided and ba	ous-Time Periodic ourier Transform, roblems) , videos 08 Hrs
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc Continuous-Time Non Periodic S Teaching Learning Method: RBT Level: Properties of Fourier Transf	als: odic signals: The Discrete-Time Non Periodic s ignals: The Fourier Transf Chalk and Talk, power po L1, L2, L3, L4 Module-4 form: Linearity, Symme	ignals: The Discrete-Time F form. (Definition and basic proton presentation, animations, a	ous-Time Periodic ourier Transform, roblems) , videos 08 Hrs y shift, Scaling,
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc Continuous-Time Non Periodic S Teaching Learning Method: RBT Level: Properties of Fourier Transf Differentiation and Integration,	als: odic signals: The Discrete-Time Non Periodic s ignals: The Fourier Transf Chalk and Talk, power per L1, L2, L3, L4 Module-4 form: Linearity, Symme	ignals: The Discrete-Time F form. (Definition and basic proton presentation, animations, a	ous-Time Periodic ourier Transform, roblems) , videos 08 Hrs y shift, Scaling,
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc Continuous-Time Non Periodic S Teaching Learning Method: RBT Level: Properties of Fourier Transf Differentiation and Integration, (Statement and Proof)	als: odic signals: The Discrete-Time Non Periodic s ignals: The Fourier Transf Chalk and Talk, power per L1, L2, L3, L4 Module-4 form: Linearity, Symme Convolution and Modu	ignals: The Discrete-Time F form. (Definition and basic probint presentation, animations, etry, Time shift, Frequency alation, Parsevals relationsh	ous-Time Periodic ourier Transform, roblems) , videos 08 Hrs y shift, Scaling, ips and Duality.
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc Continuous-Time Non Periodic S Teaching Learning Method: RBT Level: Properties of Fourier Transf Differentiation and Integration, (Statement and Proof) Applications of Fourier Repre	als: odic signals: The Discrete-Terete-Time Non Periodic s ignals: The Fourier Transf Chalk and Talk, power po L1, L2, L3, L4 Module-4 form: Linearity, Symme Convolution and Modu	ignals: The Discrete-Time F form. (Definition and basic proton presentation, animations, etry, Time shift, Frequency llation, Parsevals relationsh Frequency response of LT	ous-Time Periodic ourier Transform, roblems) , videos 08 Hrs y shift, Scaling, ips and Duality. I system, Fourier
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc Continuous-Time Non Periodic S Teaching Learning Method: RBT Level: Properties of Fourier Transf Differentiation and Integration, (Statement and Proof) Applications of Fourier Repre Transform representations for per	als: odic signals: The Discrete-Time Non Periodic s ignals: The Fourier Transf Chalk and Talk, power po L1, L2, L3, L4 Module-4 form: Linearity, Symme Convolution and Modu	ignals: The Discrete-Time F form. (Definition and basic probint presentation, animations, etry, Time shift, Frequency alation, Parsevals relationsh Frequency response of LT	ous-Time Periodic ourier Transform, roblems) , videos 08 Hrs y shift, Scaling, ips and Duality. I system, Fourier als.
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc Continuous-Time Non Periodic S Teaching Learning Method: RBT Level: Properties of Fourier Transf Differentiation and Integration, (Statement and Proof) Applications of Fourier Repre Transform representations for per Teaching Learning Method:	als: odic signals: The Discrete-Time Non Periodic signals: The Fourier Transf ignals: The Fourier Transf Chalk and Talk, power po L1, L2, L3, L4 Module-4 form: Linearity, Symme Convolution and Modu esentations: Introduction, riodic signals Sampling-Sa Chalk and Talk, power po	ignals: The Discrete-Time F form. (Definition and basic proton presentation, animations, etry, Time shift, Frequency llation, Parsevals relationsh Frequency response of LT	ous-Time Periodic ourier Transform, roblems) , videos 08 Hrs y shift, Scaling, ips and Duality. I system, Fourier als.
Introduction, Discrete-Time Perio Signals: The Fourier Series, Disc Continuous-Time Non Periodic S Teaching Learning Method: RBT Level: Properties of Fourier Transf Differentiation and Integration, (Statement and Proof) Applications of Fourier Repre Transform representations for per	als: odic signals: The Discrete-Time Non Periodic s ignals: The Fourier Transf Chalk and Talk, power po L1, L2, L3, L4 Module-4 form: Linearity, Symme Convolution and Modu	ignals: The Discrete-Time F form. (Definition and basic probint presentation, animations, etry, Time shift, Frequency alation, Parsevals relationsh Frequency response of LT	ous-Time Periodic ourier Transform, roblems) , videos 08 Hrs y shift, Scaling, ips and Duality. I system, Fourier als.

The Z-Transforms: Introduction, the Z transform, properties of the region of convergence, properties of the Z-Transform, Inverse of the Z-transform.

Teaching Learning Method:	Chalk and Talk, power point presentation, animations, videos
RBT Level:	L1, L2, L3, L4

Course outcomes:

At the end of the course the student will be able to:

CO1. Demonstrate an understanding of continuous-time and discrete-time signals and perform basic operations on signals, classify systems based on their properties.

CO2. Analyse and solve time domain representations for LTI Systems and also able to classify the LTI system based on the properties.

CO3. Understand the fundamental concepts of Fourier series, Fourier transforms, and their significance in signal analysis. Apply Fourier analysis techniques to solve problems.

CO4. Demonstrate a thorough knowledge of the key properties of the Fourier Transform, including linearity, time shifting, frequency shifting, and scaling. Apply convolution and modulation theorems to solve problems involving the multiplication of signals in the time domain.

CO5. Apply the Z-transform to analyse discrete-time signals.

Suggested Learning Resources:

Text Books:

1: Simon Haykin and Barry Van Veen, "Signals and Systems", 2nd Edition, John Wiley & Sons, Oct 2002.

Reference Books:

1: Alan V Oppenheim, Alan S, Willsky and A Hamid Nawab, "Signals and Systems" Pearson Education Asia / PHI, 2nd edition, 1997. Indian Reprint 2002.

2: Michael Roberts, "Fundamentals of Signals & Systems", 2nd edition, Tata McGraw-Hill, 2010.

3: V. Krishnaveni and A. Rajeswari, "Signals and Systems", Wiley India, Reprint 2012.

Activity Based Learning (Suggested Activities in Class)/ Practical Based learning

Activity 1: Interactive Demos and Simulations: Use interactive software or online tools to demonstrate signal transformations, system responses, and other concepts. Encourage students to manipulate parameters and observe the effects in real-time.

Activity 2: Signal Processing Workshops: Organize workshops where students work in groups to process and analyze real signals (audio, images) using software like MATLAB.

Activity 3: Case Studies: Present real-world case studies where understanding Signals and Systems is crucial. Examples include audio compression (MP3), image compression (JPEG), or equalization in audio systems.

							CO-P	O Ma	pping						
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	3	2	1									2	3	1	
CO2	3	2	2									2	3	1	
CO3	3	2	2	2								2	3	1	
CO4	3	2	2	2								2	3	1	
CO5	3	2	2	2								2	3	1	

High-3, Medium-2, Low-1

SE	NSORS AND INSTRUMENT	ATION	
Course Code:	22ECT306B	CIE Marks:	50
Teaching Hours/Week (L:T:P:S)): 3:0:0:0	SEE Marks:	50
Total Hours of Pedagogy:	39	Total Marks:	100
Credits:	03	Exam Hours:	03
Course objectives:		·	·
This course will enable students to			
	cteristics, classification of differe		
• 1	ment and the operation of different		
	meters, Voltmeters and Multime		
4. principle of operation of di	igital measuring instruments and	Bridges.	
	Module-1		08 hrs
INTRODUCTION: introductio	1	rinciples, classification,	parameters,
Environmental parameters, Charac			
MECHANICAL AND ELECTR		· 1	-
Strain gauge, Inductive sensors,	, capacitive sensors, Force/stre	ess sensors using Quartz	Resonators,
Ultrasonic sensors. TEXT 1			
Teaching Learning Method:	Chalk and talk method, PowerF	Point Presentation	
RBT Level:	L1, L2, L3		
	Module-2		07 hrs
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THERMAL SENSORS: Introduc	ction, Gas thermometric sensors,	, I nermai expansion type t	nermometric
sensors, Dielectric constant and	l refractive index thermo sens	sors. Nuclear thermometer	er, magnetic
sensors, Dielectric constant and thermometer, Resistance change	l refractive index thermo sens	sors. Nuclear thermometer	er, magnetic
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1	l refractive index thermo sens type thermometric sensors, the	sors. Nuclear thermomete ermo emf sensors, Thern	er, magnetic
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method:	l refractive index thermo sens type thermometric sensors, the Chalk and talk method, PowerF	sors. Nuclear thermomete ermo emf sensors, Thern	er, magnetic
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1	l refractive index thermo sens type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3	sors. Nuclear thermomete ermo emf sensors, Thern	er, magnetic nal radiation
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level:	l refractive index thermo sens type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation	er, magnetic nal radiation 08 hrs
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive	er, magnetic nal radiation 08 hrs sensors, Hall
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance and	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle nd eddy current sensors, Angul	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle and eddy current sensors, Angul flow meter, Switching magnetic se	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance and current sensors, Electromagnetic for Teaching Learning Method:	I refractive index thermo sens type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle Ind eddy current sensors, Angul low meter, Switching magnetic s Chalk and talk method, PowerF	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f	I refractive index thermo sens type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle Ind eddy current sensors, Angul low meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy XT 1
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f Teaching Learning Method: RBT Level:	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle I and eddy current sensors, Angul low meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy XT 1 08 hrs
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f Teaching Learning Method: RBT Level: Principles of Measurement: St	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle I and eddy current sensors, Angul low meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in I	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy XT 1 08 hrs Static Error.
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f Teaching Learning Method: RBT Level:	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle I and eddy current sensors, Angul low meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in I	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy XT 1 08 hrs Static Error.
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance and current sensors, Electromagnetic f Teaching Learning Method: RBT Level: Principles of Measurement: St	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle Ind Idow meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-3 Idow meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in Inge voltmeter. Ammeters: DC A	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of mmeter, Multi-range Amn	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy XT 1 08 hrs Static Error. neter. Digital
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f Teaching Learning Method: RBT Level: Principles of Measurement: St Voltmeters: Introduction, Multi ra Voltmeter: Ramp Technique, Dual Approximations type DVM. TEX	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle I and eddy current sensors, Angul low meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in I ange voltmeter. Ammeters: DC A slope integrating Type DVM, Dir	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of mmeter, Multi-range Amn	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy XT 1 08 hrs Static Error. neter. Digital
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance and current sensors, Electromagnetic f Teaching Learning Method: RBT Level: Principles of Measurement: St Voltmeters: Introduction, Multi ra Voltmeter: Ramp Technique, Dual	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle I and eddy current sensors, Angul low meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in I ange voltmeter. Ammeters: DC A slope integrating Type DVM, Dir	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of mmeter, Multi-range Amn rect Compensation type an	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy XT 1 08 hrs Static Error. neter. Digital
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f Teaching Learning Method: RBT Level: Principles of Measurement: St Voltmeters: Introduction, Multi ra Voltmeter: Ramp Technique, Dual Approximations type DVM. TEX	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle I and eddy current sensors, Angul Iow meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in I ange voltmeter. Ammeters: DC A slope integrating Type DVM, Dir T 2	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of mmeter, Multi-range Amn rect Compensation type an	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy XT 1 08 hrs Static Error. neter. Digital
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f Teaching Learning Method: RBT Level: Principles of Measurement: St Voltmeters: Introduction, Multi ra Voltmeter: Ramp Technique, Dual Approximations type DVM. TEX Teaching Learning Method: RBT Level:	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle I nd eddy current sensors, Angul Iow meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in I nge voltmeter. Ammeters: DC A slope integrating Type DVM, Dir T 2 Chalk and talk method, PowerF L1, L2, L3 Module-5	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of mmeter, Multi-range Amn rect Compensation type an Point Presentation	er, magnetic nal radiation 08 hrs sensors, Hall ducer, Eddy XT 1 08 hrs Static Error. neter. Digital d Successive 08 hrs
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f Teaching Learning Method: RBT Level: Principles of Measurement: St Voltmeters: Introduction, Multi ra Voltmeter: Ramp Technique, Dual Approximations type DVM. TEX Teaching Learning Method:	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle I nd eddy current sensors, Angul Iow meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in I nge voltmeter. Ammeters: DC A slope integrating Type DVM, Dir T 2 Chalk and talk method, PowerF L1, L2, L3 Module-5	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of mmeter, Multi-range Amn rect Compensation type an Point Presentation	er, magnetic nal radiation 08 hrs sensors, Hall ducer, Eddy XT 1 08 hrs Static Error. neter. Digital d Successive 08 hrs
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f Teaching Learning Method: RBT Level: Principles of Measurement: St Voltmeters: Introduction, Multi ra Voltmeter: Ramp Technique, Dual Approximations type DVM. TEX Teaching Learning Method: RBT Level:	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle Ind eddy current sensors, Angul low meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in I nge voltmeter. Ammeters: DC A slope integrating Type DVM, Dir T 2 Chalk and talk method, PowerF L1, L2, L3 Module-5 n, Digital Multimeter, Digital free	sors. Nuclear thermomete ermo emf sensors, Therm Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of mmeter, Multi-range Amn rect Compensation type an Point Presentation quency meters, Digital mea	er, magnetic nal radiation 08 hrs sensors, Hall sducer, Eddy XT 1 08 hrs Static Error. neter. Digital d Successive 08 hrs asurement of
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f Teaching Learning Method: RBT Level: Principles of Measurement: St Voltmeters: Introduction, Multi ra Voltmeter: Ramp Technique, Dual Approximations type DVM. TEX Teaching Learning Method: RBT Level: Digital Instruments: Introduction	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle I nd eddy current sensors, Angul low meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in I nge voltmeter. Ammeters: DC A slope integrating Type DVM, Dir T 2 Chalk and talk method, PowerF L1, L2, L3 Module-5 n, Digital Multimeter, Digital free on generator, Block diagram of	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of mmeter, Multi-range Amn rect Compensation type an Point Presentation Quency meters, Digital mea Coscilloscope. Bridges: V	er, magnetic nal radiation 08 hrs sensors, Hall ducer, Eddy XT 1 08 hrs Static Error. neter. Digital d Successive 08 hrs asurement of Wheatstone's
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance and current sensors, Electromagnetic f Teaching Learning Method: RBT Level: Principles of Measurement: St Voltmeters: Introduction, Multi ra Voltmeter: Ramp Technique, Dual Approximations type DVM. TEX Teaching Learning Method: RBT Level: Digital Instruments: Introduction time. Signal Generators: Function Bridge, Capacitance and Inductance	l refractive index thermo sens type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle I nd eddy current sensors, Angul low meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in I nge voltmeter. Ammeters: DC A slope integrating Type DVM, Dir T 2 Chalk and talk method, PowerF L1, L2, L3 Module-5 n, Digital Multimeter, Digital free on generator, Block diagram of ce Comparison bridge, Maxwell'	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of mmeter, Multi-range Amn rect Compensation type an Point Presentation quency meters, Digital mea Coscilloscope. Bridges: V 's bridge, Wien's bridge. T	er, magnetic nal radiation 08 hrs sensors, Hall ducer, Eddy XT 1 08 hrs Static Error. neter. Digital d Successive 08 hrs asurement of Wheatstone's
sensors, Dielectric constant and thermometer, Resistance change sensors. TEXT 1 Teaching Learning Method: RBT Level: MAGNETIC SENSORS: Introdu effect and sensors, Inductance an current sensors, Electromagnetic f Teaching Learning Method: RBT Level: Principles of Measurement: St Voltmeters: Introduction, Multi ra Voltmeter: Ramp Technique, Dual Approximations type DVM. TEX Teaching Learning Method: RBT Level: Digital Instruments: Introduction time. Signal Generators: Function	I refractive index thermo sense type thermometric sensors, the Chalk and talk method, PowerF L1, L2, L3 Module-3 action, Sensors and the principle I nd eddy current sensors, Angul low meter, Switching magnetic s Chalk and talk method, PowerF L1, L2, L3 Module-4 tatic Characteristics, Error in I nge voltmeter. Ammeters: DC A slope integrating Type DVM, Dir T 2 Chalk and talk method, PowerF L1, L2, L3 Module-5 n, Digital Multimeter, Digital free on generator, Block diagram of	sors. Nuclear thermomete ermo emf sensors, Thern Point Presentation behind, Magneto resistive lar/rotary movement trans sensor, SQUID sensor. TE Point Presentation Measurement, Types of mmeter, Multi-range Amn rect Compensation type an Point Presentation quency meters, Digital mea Coscilloscope. Bridges: V 's bridge, Wien's bridge. T	er, magnetic nal radiation 08 hrs sensors, Hall ducer, Eddy XT 1 08 hrs Static Error. neter. Digital d Successive 08 hrs asurement of Wheatstone's

Course outcomes:

At the end of the course the student will be able to:

CO 1: Understand operation principle, classification, characteristics of sensors, mechanical and electrical sensors

CO 2: Understand operation principle, different types, characteristics of thermal sensors.

CO 3: Understand operation principle, different types, characteristics of magnetic sensors.

CO 4: Analyse principle of measurement, operation of different ammeters and voltmeters.

CO 5: Analyse the operation, classification, different types of digital instruments.

Suggested Learning Resources:

Text Books:

1. D Patranabis, "Sensors and Transducers", PHI Learning Private Limited, New Delhi – 110 001, Second Edition 2010

2. H. S. Kalsi, "Electronic Instrumentation", 3rd Edition, McGraw Hill, 2012

Reference Books:

1. David A. Bel "Electronic Instrumentation & Measurements", 2nd Edition, Oxford University Press PHI, 2006

Web Links:

http://nptel.ac.in/courses

Activity Based Learning (Suggested Activities in Class)/ Practical Based learning

- 1. Seminar on different types of sensors
- 2. Seminar on different measuring instruments

CO-PO Mapping

	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	3	2							1	1					
CO2	3	2							1	1					
CO3	3	2							1	1					
CO4	3	2							1	1					
CO5	3	2							1	1					
High-3	, Mediu	ım-2, L	ow-1												

COMI	PUTER	ORGANIZATION AND AR	CHITECTURE		
Course Code:		22ECT306C	CIE Marks:	50	
Teaching Hours/Week (L:T:P	?:S):	3:0:0:0	SEE Marks:	50	
Total Hours of Pedagogy:	/	39	Total Marks:	100	
Credits:		03	Exam Hours:	03hrs	
Course objectives:					
1. Understand the meaning of b			achine instruction	s and program	ns.
2. Analyze addressing modes a					
3. Compute the quantitative particular of the second secon			output organizatio	n.	
4. Associate the concepts of me					
5.understanding the concept of	simple		n two controls.		001
	C	Module-1			<u>00 hrs</u>
Basic Structure of Computer					
Structures, Software, Performa	nce – P	rocessor Clock, Basic Perfe	ormance Equation	(upto 1.6.2 of	f Chap 1
of Text).					
Machine Instructions and Pr	ogram	s: Numbers, Arithmetic Op	erations and Chara	acters, IEEE s	standard
for Floating point Numbers, I	Memory	V Location and Addresses,	Memory Operati	ons, Instructi	ons and
Instruction Sequencing, (upto 2	2.4.6 of	Chap 2 and 6.7.1 of Chap 6	6 of Text).		
Teaching Learning Method:		and talk method, Power po	oint presentation		
RBT Level:	L1,L2				
		Module-2			0 hrs
Addressing Modes, Assembly	' Langı	lage, Basic Input and Ol	utput Operations,	Stacks and	Queues,
Subroutines, Additional Instruc				2 of text).	
Teaching Learning Method:	Chalk	and talk method, Power po	oint presentation		
RBT Level:	L1,L2	/			
		Module-3			0 hrs
Input/Output Organization:			_		-
Disabling Interrupts, Handling	1	, U	evice Requests, Di	rect Memory	Access,
(upto 4.2.4 and 4.4 except 4.4.1					
Teaching Learning Method:	Chalk	and talk method, Power po	oint presentation		
RBT Level:	L1,L2				
		Module-4			0 hrs
Memory System: Basic Cone	1 /		U		2
chips, Static memories, Asynch	ronous	DRAMS, Read Only Memo	ories, Cash Memori	es, Virtual Me	emories,
Secondary Storage-Magnetic H	Iard Dis	sks (5.1, 5.2, 5.2.1, 5.2.2, 5	.2.3, 5.3, 5.5 (exce	pt 5.5.1 to 5.3	5.4), 5.7
(except 5.7.1), 5.9, 5.9.1 of Cha	ap 5 of '	Text).			
Teaching Learning Method:	Chalk	and talk method, Power po	oint presentation		
RBT Level:	L1,L2	.,L3	-		
		Module-5			00 hrs
Basic Processing Unit: Some	Fundam	ental Concepts, Execution	of a Complete Inst	ruction, Mult	iple Bus
Organization, Hardwired Contr Text).	ol, Mic	roprogrammed Control (up	to 7.5 except 7.5.1	to 7.5.6 of C	hap 7 of
,	Ch-11-	and talls mathed Damas	int procentation		
Teaching Learning Method:		and talk method, Power po	oint presentation		
RBT Level:	L1,L2	.,LJ			

Course outcomes:

At the end of the course the student will be able to:

CO1. Explain the basic organization of a computer system.

CO2. Describe the addressing modes, instruction formats and program control statement.

CO3. Explain different ways of accessing an input/ output device including interrupts.

CO4. Illustrate the organization of different types of semiconductor secondary storage memories.

CO5. Illustrate simple processor organization based on hardwired control and micro programmed control.

Suggested Learning Resources:

Text Books:

1: Carl Hamacher, Zvonko Vranesic, Safwat Zaky: Computer Organization, 5th Edition, Tata McGraw Hill, 2002.

Reference Books (if required)

1: David A. Patterson, John L. Hennessy: Computer Organization and Design – The Hardware / Software Interface ARM Edition, 4th Edition, Elsevier, 2009.

2: William Stallings: Computer Organization & Architecture, 7th Edition, PHI, 2006.

3: Vincent P. Heuring & Harry F. Jordan: Computer Systems Design and Architecture, 2nd Edition, Pearson Education, 2004.

Web Links: https://archive.nptel.ac.in/courses/106/105/106105163/

Activity Based Learning (Suggested Activities in Class)/ Practical Based learning Activity 1: Programming Assignments / Mini Projects can be given

		202	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	3	2			2							1			
CO2	3	2			2							1			
CO3	3	2			2							1			
CO4	3	2		2	2							1			
CO5	3	2			3							1			
High-3, M	ledium	1-2, L	ow-1												

LIC (Linear Integrated Circuits) Lab using PSPICE

Cour	se Code: 22ECL308A	CIE Marks: 50									
Teac	hing Hours/Week (L:T:P: S): 0:0:2:0	SEE Marks: 50									
Cred	its: 1	Exam Hours:100									
Cour • • •	rse objectives: To gain hands on experience in designing To learn simulation software used to simu To learn fundamental principles of applic. To design the applications of linear integr	ations of linear integrated circuits.									
SI.		s using PSPICE									
No	NOTE: Every experiment has to be designed, circuit to be drawn / constructed and executed in the specified software. Results are also to be noted and inferred.										
	Note: Standard design	n procedure to be adopted.									
1	To realize using op-amp an Inverting Amp	To realize using op-amp an Inverting Amplifier and Non-Inverting Amplifier									
2	To realize using op-amps i) Summing Am	plifier ii)Difference amplifier									
3	To realize using op-amps an Instrumentation	on Amplifier									
4	To realize using op-amps i) Differentiator	ii)Integrator									
5	To realize using op-amps a Full wave Prec	ision Rectifier									
6	To realize using op-amps i) Inverting and Non-Inverting Zero (ii) Positive and Negative Voltage leve	-									
7	To realize using op-amp an Inverting Schn	nitt Trigger									
8	To realize using op-amp an Astable Multiv	vibrator									
9	To design and implement using op-ampsi) Butterworth I & II order Low Passii) Butterworth I & II order High Pass										

10	To design and implement using op-amp a RC Phase Shift Oscillator
11	To design and implement Mono-stable Multivibrator using 555 timer
12	To design and implement 4 - bit R-2R Digital to Analog Converter

Course outcomes (Course Skill Set):

After studying this course, students will be able to;

CO1: Sketch/draw schematics of linear integrated circuit applications.

CO2: Design the applications of LIC for the given specifications.

CO3: Demonstrate the fundamentals of linear integrated circuits and their applications using PSPICE tool.

CO-PO Mapping

	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	3							1	2	2			3	2	
CO2	3	3						1	2	2			3	2	
CO3	3	3			2			1	2	2			3	2	

High-3, Medium-2, Low-1

IV Semester

E	NGINEERING ELECTR	OMAGNETICS	
Course Code:	22ECT401	CIE Marks:	50
Teaching Hours/Week (L:T:P:		SEE Marks:	50
Total Hours of Pedagogy:	40	Total Marks:	100
Credits:	03	Exam Hours:	03
Course objectives:			
1. Understanding the conc problems using coulomb	's law, gauss law.	ields for EM waves and to anal	-
•		ential difference and capacitance.	
_	_	pisson's equations and to acquire	knowledge of
their practical application	18.		
5. To understand the impor	•	on and applying them for time va in free space & dielectrics and	
for time varying fields.			
	Module-1		08 hrs
Electrostatics: Coulomb's Lav	v and electric field intens	sity, Field due to continuous vo	olume charge
distribution, Field of a line chan	ge. Field of a sheet of cha	arge. Electric flux density, Gauss	s' law and its
applications. Divergence, Maxw	_		
8	Lecture-based learning an	d Group learning	
RBT Level:	L1, L2		1
	Module-2		08 hrs
		nt charge in an electric field, The	-
-	-	tial field of a point charge, Poten	tial gradient,
Energy density in an electrostati	c field. TEXT 1		
Teaching Learning Method: RBT Level:	Lecture-based learning an L1, L2	d Group learning	
	Module-3		08 hrs
theorem.	vart law and its applicatio	sson's and Laplace's Equations	-
	Lecture-based learning and Gro L1, L2	oup learning	
RBT Level:	Module-4		08 hrs
differential current elements.	a moving charge and	differential current element, Fo	orce between
-	form, Boundary condition	day's law, Displacement curren ons for perfect dielectric materia	
Teaching Learning Method: RBT Level:	Lecture-based learning an L1, L2,L3	d Group learning	
	Module-5		08 hrs
Electromagnetic waves: Wav conductors – skin effect, Wave j	1 1 0	pace and dielectrics, Propagat e ratio. TEXT 1	ion in good

Teaching Learning Method:	Lecture-based learning and Group learning
RBT Level:	L1, L2, L4

Course outcomes:

At the end of the course the student will be able to:

CO1. Able to define electrostatic field and its laws such as Coulomb's law, Gauss' law & Divergence.

- CO2. Able to understand energy expanded, potential difference, Potential gradient & Energy density in electrostatic field
- CO3. Able to apply and solve Ampere's circuital law and apply Maxwell's equations in wave propagation.

CO4. Able to analyze magnetic forces and Maxwell's equations.

CO5. Able to understand propagation of waves in different medium with its fundamental concepts of skin effect and standing wave ratio .

Suggested Learning Resources:

Text Books:

1. William H Hayt Jr. and John A Buck, "Engineering Electromagnetics", 8th edition, McGraw-Hill, 2012Collin RE. Foundations for microwave engineering. John Wiley & Sons; 2007.

2. David K Cheng, "Field and Wave Electromagnetics", 2nd edition, Pearson Education Asia, Indian Reprint – 2001Annapurna Das, Sisir K Das, Microwave Engineering, TMH Publication, 2001

Reference Books

1. John Krauss and Daniel A Fleisch, "Electromagnetics with Applications", 5th edition, McGraw-Hill, 1999Microwave Devices and circuits- Liao / Pearson Education. 1992

2. Edward C. Jordan and Keith G Balmain,, "Electromagnetic Waves and Radiating Systems", 2nd Edition, Prentice – Hall of India / Pearson Education, Reprint – 2002M.Kulkarni., "Microwave devices and Radar Engg."Umesh Publications, 2011

Web Links:

1. www.nptel.in

2.www.google.com , david k cheng fields and waves electromagnetics pdf download

3.www.google.com, william h hayt engineering electromagnetics pdf

4.www.youtube/electromagnaticsforengineers

Activity Based Learning (Suggested Activities in Class)/ Practical Based learning 1: Creating physical modules

2: Exploring new technologies and presenting

							CO-P	O Maj	pping						
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	3	2												2	
CO2	3	3	2											2	
CO3	3	2	2											2	
CO4	3	3	2											2	
CO5	3	3	2										2	2	
High-3	, Medi	um-2, I	low-1												

IV Semester

PRINUI	PLES OF COMMUNICATION S	YSTEMS	
Course Code:	22ECU402	CIE Marks:	50
Teaching Hours/Week (L:T:P:S)	3: 0: 2: 0	SEE Marks:	50
Total Hours of Pedagogy:	52	Total Marks:	100
Credits:	04	Exam Hours:	03
Course objectives:	I	- 1	- 1
1. Understand and analyse of	concepts of Analog Modulation s	chemes viz; AM,	FM., Low pass
sampling and Quantization	as a random process.		-
2. Understand and analyse co	ncepts digitization of signals viz; sa	mpling, quantizing	and encoding.
-	t in the presence of channel induce		-
analog modulated signals.	-		
4. Evolve the concept of quar	tization noise for sampled and enco	oded signals and stu	udy the concepts
of reconstruction from thes	_	C	•
	Module-1		09 hrs
Amplitude Modulation: Introduc	tion, Amplitude Modulation: Time	& Frequency Don	nain description,
switching modulator, Envelop dete	ctor.		_
Double Side Band-Suppressed (Carrier Modulation: Time and Fr	equency Domain d	escription, Ring
modulator, Coherent detection, Co	stas Receiver, Quadrature Carrier M	fultiplexing.	
SINGLE SIDE-Band and Vest	igial Sideband Methods of Mo	dulation: SSB M	odulation, VSB
	, Frequency Division Multiplexing		
Teaching Learning Method:	Chalk and talk method, Power Poi		
RBT Level:	L1, L2, L3		
	Module-2		08 hrs
ANGLE MODULATION: Basic	definitions, Frequency Modulation:	Narrow Band FM,	Wide Band FM,
	ignals, Generation of FM Signals,		
	ed Loop: Nonlinear model of PLL,		-
Heterodyne Receiver.	•		L. The Super
			L. The Super
-	Chalk and talk method, Power Poi	nt Presentation, You	
Teaching Learning Method:	Chalk and talk method, Power Poi L1, L2, L3	nt Presentation, You	
-	L1, L2, L3	nt Presentation, You	uTube videos.
Teaching Learning Method: RBT Level:	L1, L2, L3 Module-3	·	
Teaching Learning Method: RBT Level: NOISE: Shot Noise, Thermal nois	L1, L2, L3 Module-3 e, White Noise, Noise Equivalent E	Bandwidth.	uTube videos. 08 hrs
Teaching Learning Method: RBT Level: NOISE: Shot Noise, Thermal nois NOISE IN ANALOG MODULA	L1, L2, L3 Module-3 e, White Noise, Noise Equivalent E ATION: Introduction, Receiver M	Bandwidth. Iodel, Noise in DS	aTube videos. 08 hrs B-SC receivers.
Teaching Learning Method: RBT Level: NOISE: Shot Noise, Thermal nois NOISE IN ANALOG MODULA Noise in AM receivers, Threshold	L1, L2, L3 Module-3 e, White Noise, Noise Equivalent E ATION: Introduction, Receiver M effect, Noise in FM receivers, Capt	Bandwidth. Iodel, Noise in DS	uTube videos. 08 hrs B-SC receivers.
Teaching Learning Method: RBT Level: NOISE: Shot Noise, Thermal nois NOISE IN ANALOG MODULA Noise in AM receivers, Threshold threshold reduction, Pre-emphasis	L1, L2, L3 Module-3 e, White Noise, Noise Equivalent E ATION: Introduction, Receiver M effect, Noise in FM receivers, Capt and De-emphasis in FM.	Bandwidth. Iodel, Noise in DS ure effect, FM three	uTube videos. 08 hrs B-SC receivers. shold effect, FM
Teaching Learning Method: RBT Level: NOISE: Shot Noise, Thermal nois NOISE IN ANALOG MODULA Noise in AM receivers, Threshold threshold reduction, Pre-emphasis Teaching Learning Method:	L1, L2, L3 Module-3 e, White Noise, Noise Equivalent E ATION: Introduction, Receiver M effect, Noise in FM receivers, Capt and De-emphasis in FM. Chalk and talk method, Power Poi	Bandwidth. Iodel, Noise in DS ure effect, FM three	uTube videos. 08 hrs B-SC receivers. shold effect, FM
Teaching Learning Method: RBT Level: NOISE: Shot Noise, Thermal nois NOISE IN ANALOG MODULA Noise in AM receivers, Threshold threshold reduction, Pre-emphasis	L1, L2, L3 Module-3 e, White Noise, Noise Equivalent E ATION: Introduction, Receiver M effect, Noise in FM receivers, Capt and De-emphasis in FM. Chalk and talk method, Power Poi L1, L2, L3	Bandwidth. Iodel, Noise in DS ure effect, FM three	uTube videos. 08 hrs B-SC receivers. shold effect, FM uTube videos.
Teaching Learning Method: RBT Level: NOISE: Shot Noise, Thermal nois NOISE IN ANALOG MODULA Noise in AM receivers, Threshold threshold reduction, Pre-emphasis Teaching Learning Method: RBT Level:	L1, L2, L3 Module-3 e, White Noise, Noise Equivalent E ATION: Introduction, Receiver M effect, Noise in FM receivers, Capt and De-emphasis in FM. Chalk and talk method, Power Poi L1, L2, L3 Module-4	Bandwidth. Iodel, Noise in DS ure effect, FM three nt Presentation, You	uTube videos. 08 hrs B-SC receivers. shold effect, FM uTube videos. 07 hrs
Teaching Learning Method: RBT Level: NOISE: Shot Noise, Thermal nois NOISE IN ANALOG MODULA Noise in AM receivers, Threshold threshold reduction, Pre-emphasis Teaching Learning Method: RBT Level: SAMPLING AND QUANTIZA	L1, L2, L3 Module-3 e, White Noise, Noise Equivalent E ATION: Introduction, Receiver M effect, Noise in FM receivers, Capt and De-emphasis in FM. Chalk and talk method, Power Poi L1, L2, L3 Module-4 FION: Introduction, Why Digitized	Bandwidth. Jodel, Noise in DS ure effect, FM three nt Presentation, You e Analog Sources?	uTube videos. 08 hrs B-SC receivers. shold effect, FM uTube videos. 07 hrs The Low Pass
Teaching Learning Method: RBT Level: NOISE: Shot Noise, Thermal noise NOISE IN ANALOG MODULA Noise in AM receivers, Threshold threshold reduction, Pre-emphasise Teaching Learning Method: RBT Level: SAMPLING AND QUANTIZA Sampling Process, Pulse Amplitud	L1, L2, L3 Module-3 e, White Noise, Noise Equivalent E ATION: Introduction, Receiver M effect, Noise in FM receivers, Capt and De-emphasis in FM. Chalk and talk method, Power Poi L1, L2, L3 Module-4 TION: Introduction, Why Digitize e Modulation. Time Division Multip	Bandwidth. Jodel, Noise in DS ure effect, FM three nt Presentation, You e Analog Sources?	uTube videos. 08 hrs B-SC receivers. shold effect, FM uTube videos. 07 hrs The Low Pass
Teaching Learning Method: RBT Level: NOISE: Shot Noise, Thermal nois NOISE IN ANALOG MODULA Noise in AM receivers, Threshold threshold reduction, Pre-emphasis Teaching Learning Method: RBT Level: SAMPLING AND QUANTIZAT Sampling Process, Pulse Amplitud Generation of PPM Waves, Detect	L1, L2, L3 Module-3 e, White Noise, Noise Equivalent E ATION: Introduction, Receiver M effect, Noise in FM receivers, Capt and De-emphasis in FM. Chalk and talk method, Power Poi L1, L2, L3 Module-4 TION: Introduction, Why Digitize e Modulation. Time Division Multiplied to the second s	Bandwidth. lodel, Noise in DS ure effect, FM three nt Presentation, You e Analog Sources? plexing, Pulse-Posit	uTube videos. 08 hrs B-SC receivers. shold effect, FM uTube videos. 07 hrs The Low Pass tion Modulation,
Teaching Learning Method: RBT Level: NOISE: Shot Noise, Thermal noise NOISE IN ANALOG MODULA Noise in AM receivers, Threshold threshold reduction, Pre-emphasise Teaching Learning Method: RBT Level: SAMPLING AND QUANTIZA Sampling Process, Pulse Amplitud	L1, L2, L3 Module-3 e, White Noise, Noise Equivalent E ATION: Introduction, Receiver M effect, Noise in FM receivers, Capt and De-emphasis in FM. Chalk and talk method, Power Poi L1, L2, L3 Module-4 TION: Introduction, Why Digitize e Modulation. Time Division Multip	Bandwidth. lodel, Noise in DS ure effect, FM three nt Presentation, You e Analog Sources? plexing, Pulse-Posit	uTube videos. 08 hrs B-SC receivers. shold effect, FM uTube videos. 07 hrs The Low Pass tion Modulation,

		Module-5	07 hrs								
SAMPL	ING AND QUANTIZAT	TION (Contd): The Quantization Random Process, Qua	ntization Noise,								
	-	ling, Quantization, Encoding, Regeneration, Decod									
-	•	application examples - (a) Video + MPEG (Text1:7.11) a	nd (b) Vocoders								
	ction 6.8 of Reference Bo										
-	g Learning Method:	Chalk and talk method, Power Point Presentation, You	Tube videos.								
RBT Lev	vel:	L1, L2, L3									
	DI	ACTICAL COMPONENT OF IDCC									
Sl.No.		ACTICAL COMPONENT OF IPCC Experiments									
1	Generation and demodulation of Amplitude modulation (AM) wave.										
		fation of Amphtude modulation (Aw) wave.									
2	Generation and demodulation of Double side band supressed carrier (DSB-SC) wave.										
3	Generation and demodulation of Fraguency modulation (FM) wave										
4	Generation and demodulation of Frequency modulation (FM) wave.										
4	Phase locked loop Synthesis										
5	Generation and demodu	lation of Pulse Amplitude Modulation.									
6	Generation and demodu	lation of Pulse Position Modulation.									
7	Time division multiplex	ing of two band limited signals.									
8	Illustrate the process of	sampling and reconstruction of low pass signals using N	Matlab.								
9	Illustration of Pulse Cod	le Modulation using Matlab									
10	Illustration of Delta Mo	dulation using Matlab.									
11	Noise in AM receiver u	sing (Matlab/ Simulink/Scilab)									
12	Noise in FM receiver us	sing (Matlab/ Simulink/Scilab)									

Course outcomes:

At the end of the course the student will be able to:

CO1. Understand the amplitude and frequency modulation techniques and analyze the perform time and frequency domain transformations.

CO2. Identify the schemes for amplitude and frequency modulation and demodulation of analog signals and compare the performance.

CO3. Characterize the influence of channel noise on analog modulated signals.

CO4. Understand the characteristics of pulse amplitude modulation, pulse position modulation and pulse code modulation systems.

CO5. Illustration of digital formatting representations used for Multiplexers, Vocoders and Video transmission.

Suggested Learning Resources:

Text Books:

1: Simon Haykins & Moher, Communication Systems, 5th Edition, John Wiley, India Pvt. Ltd, 2010, ISBN 978 - 81 - 265 - 2151 - 7.

2: Simon Haykins, An Introduction to Analog and Digital Communication, John Wiley India Pvt. Ltd., 2008, ISBN 978–81–265–3653–5.

Reference Books:

1: B P Lathi and Zhi Ding, Modern Digital and Analog Communication Systems, Oxford University Press., 4th edition, 2010, ISBN: 97801980738002.

2: H Taub & D L Schilling, Principles of Communication Systems, TMH, 2011.

Activity Based Learning (Suggested Activities in Class)/ Practical Based learning

- Quizzes
- Surprise Tests
- Assignments
- Seminars
- Micro Projects can be given to improve the skills

CO-PO Mapping

	P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PSO1	PSO2	PSO3
CO1	3	2	1					1	1	1		1	3	3	
CO2	3	2	1					1	1	1		1	3	3	
CO3	3	2	1					1	1	1		1	3	3	
CO4	3	2	1					1	1	1		1	3	3	
CO5	3	2	1					1	1	1		1	3	3	
High-3	, Medi	um-2, 🛛	Low-1												

IV Semester

МС	DERN CONTROL SYSTEM	S								
Course Code:	22ECU403	CIE Marks:	50							
Teaching Hours/Week (L:T:P:S):	2:2:2:0	SEE Marks:	50							
Total Hours of Pedagogy:	52 Hours	Total Marks:	100							
Credits:	4 (2:1:1)	Exam Hours:	03 Hrs							
Course objectives:										
1.To familiarize the basic laws, source	e transformation, source shifting	and network analys	is techniques.							
2. To understand the network theorem	-	•	-							
3. To understand the transient behavior		-								
4. To Apply Laplace transforms for th	e analysis of electrical circuits.									
5. To evaluate the two port network pa	-	iits.								
	Module-1		08 hrs							
Introduction to Control Systems: O	pen loop control system, Closed	l loop control systen	n, Examples of							
Control System.										
Mathematical Modelling: Introduction	on, Differential equations of Phy	ysical Systems (Only	Electrical and							
Mechanical Systems), Transfer function		• • •								
Text Book1: 1.1, 1.3, 2.1, 2.2, 2.5.										
Teaching Learning Method:	Chalk and Roard Problem Ba	ad Learning								
Teaching Learning Method:Chalk and Board, Problem Based Learning RBT Level: L1, L2, L3, L4										
KDT Level.	Module-2		08 hrs							
Block Diagrams: Block Diagram Mo		Applications	00 11 5							
Signal Flow Graphs: Signal-Flow Gr										
State Variable Models: Introduction,	-		fferential							
equation, signal flow graph and block	-	-								
time response and the State Transition	•	metion nom the state	equation, the							
Text Book1: 2.6, 2.7, 3.1 to 3.4, 3.6, 3										
Teaching Learning Method:	Chalk and Board, Problem Bas	sed Learning								
RBT Level:	L1, L2, L3, L4	sed Learning								
	Module-3		08 hrs							
Transient and Steady-State Respo		irst-Order Systems								
Systems, Effects of Proportional, In	-	=								
Steady-State Errors in Unity-feedback	0	Actions on System	i enormance,							
Text Book2: 5.1 to 5.3, 5.7, 5.8	Control Systems.									
Teaching Learning Method:	Chalk and Board, Problem Bas	ad Learning								
RBT Level:	L1, L2, L3, L4	sed Learning								
KDT ECVCI.	Module-4		08 hrs							
Stability of Control Systems: Routh		tability	00 11 5							
Text Book2: 5.6.	s stability efficitori, Relative s	aomy.								
The Root-Locus Method: Introduction	n The Root Locus Concent Th	e Root Locus Proced	ure Evamples							
Text Book1: 7.1 to 7.3	, The Root Locus Concept, Th		ure, Examples.							
Teaching Learning Method:	Chalk and Board, Problem Bas	sed Learning								
I LAUHINZ LUAI HINZ WITHIUU.	Chaix and Duard, FIUDICIII Da	bed Leanning								

RBT Lev	vel:	L1, L2, L3, L4							
		Module-5	08 hrs						
-	• • •	ntroduction, Correlation between Time and Frequence	uency Response, Boo						
-	perimental determination	of Transfer functions.							
ext Doc	ok3: 8.1, 8.2, 8.4, 8.6								
Teaching	g Learning Method:	Chalk and Board, Problem Based Learning							
RBT Lev	vel:	L1, L2, L3, L4							
		Iodern Control Systems	12 hrs						
	Integr	rated Laboratory Component							
		Experiments using PSPICE							
Sl.	NOTE: Every experim	ent has to be designed necessary diagrams/plots to	o be drawn /						
No	NOTE: Every experiment has to be designed, necessary diagrams/plots to be drawn / constructed and executed in the specified software. Results are also to be noted and inferred.								
		r · · · · ·							
	i	Note: Standard design procedure to be adopted.							
1	Obtain Cascaded, Parallel and Feedback closed loop transfer functions using MATLAB.								
2	Convert Transfer function to state space representation and Vice-versa.								
3	Obtain 2D and 3D plo	ts of unit step response of 2 nd order system.							
4	Find the Time Respon	se Specifications of unit step response of 2 nd orde	er System.						
5	Draw root locus using	MATLAB							
6	Draw BODE PLOTs u	sing MATLAB							
7	Study the effect of PI	controller using MATLAB							
8	Study the effect of PD	controller using MATLAB							
9	Study the effect of PII	controller using MATLAB							
10	Study of speed charact	eristics of DC motors using MATLAB.							
Course o	outcomes:								
At the en	nd of the course the stud	lent will be able to:.3							
	ptain the mathematical m	-							
C O2. Si pproach		s using graphical methods and represent the give	n system in state space						

CO3. Evaluate the system performance through time domain specifications and steady state error.

CO4. Examine stability using Routh's Criterion and Root-Locus method.

CO5. Evaluate the system performance in frequency domain.

Suggested Learning Resources: Text Books:

1 M 1 0 1 10 1 10 1 10 1

1: Modern Control Systems, Richard C. Dorf and Robert H. Bishop, Pearson, 13th Edition, 2017.

2: Modern Control Engineering, Katsuhiko Ogata, Prentice Hall, 5th Edition, 2010.

3: Control Systems Engineering, I J Nagrath and M Gopal, New Age International Publishers, 4th edition, 2006.

Activity Based Learning (Suggested Activities in Class)/ Practical Based learning

Activity 1: Quizzes

Activity 2: Seminars

Activity 3: Simulation using MATLAB

Activity 4: Case studies

CO-PO Mapping

	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3
CO1	3	3											3		
CO2	3	3											3		
CO3	3	3											3		
CO4	3	3											3		
CO5	3	3											3		
igh-3, I	Mediu	ım-2,	Low-	1											

IV Semester

	COM	IMUNICATION LA	BORATORY						
Course (Code:	22ECL404	CIE Marks:	50					
Teaching	g Hours/Week (L:T:P:S)	0: 0: 2: 0	SEE Marks:	50					
	ours of Pedagogy:	13	Total Marks:	100					
Credits:		1	Exam Hours:	3					
Course o	objectives:								
1. D	emonstrate the Analog modu	lation techniques.							
2. N	Iodel an optical communicat	ion system and study	its characteristics.						
3. S	imulate the digital communic	cation concepts and co	ompute and display various p	parameters along					
W	vith plots/figures								
4. D	esign, Demonstrate and Ana	lyze filters using op-a	mp.						
Sl. No.		Experii	nents						
	Part – A discrete Experim	ents							
1	Time division multiplexing and de-multiplexing using IC 8038								
2	Generation and detection of standard Amplitude modulation.								
3	Generation and detection of P	Pulse Amplitude modula	tion.						
4	Pre-Emphasis and De-Empha	sis Circuits							
5	Coupling and bending loss in	optical fiber communic	ation.						
6	Attenuation loss and numerical aperture in optical communication.								
	Part –B Simulation using	Simulink							
1	Design of active second order Butterworth low pass filter.								
2	Design of active second order Butterworth high pass filter.								
3	Design of active second order	Butterworth Band pass	s filter.						
4	Design of active second order	Butterworth Band elim	ination filter.						
5	Pulse Width Modulation and	Demodulation							
6	Pulse Position Modulation an	d Dama dulation							

At the end of the course the student will be able to:

CO1: Simulate the digital modulation schemes with the display of waveforms and computation of performance parameters. \cdot

CO2: Design and test the analog/digital modulation circuits/systems and display the waveforms. CO3: Design and illustrate the operation of instrumentation amplifier, LPF, HPF, DAC and oscillators using linear IC.

CO-PO Mapping

	P01	P02	P03	P04	P05	P06	P07	P08	P09	P010	P011	P012	PSO1	PSO2	PSO3
C01	3	3	2					1	1	1		1	3	3	
CO2	3	3	2					1	1	1		1	3	3	
CO3	3	3	2					1	1	1		1	3	3	
CO4	3	3	2					1	1	1		1	3	3	
CO5	3	3	2					1	1	1		1	3	3	
High-3	High-3, Medium-2, Low-1														

IV Semester

	8051 MICROCONTE	ROLLER				
Course Code:	22ECT405A	CIE Marks:	50			
Teaching Hours/Week (L:T:P:	S): 3:0:0	SEE Marks:	50			
Total Hours of Pedagogy:	40	Total Marks:	100			
Credits:	03 Exam Hours:					
Course objectives:						
This course will enable studen	ts to:					
• Understand the difference betw	veen a microprocessor and a	a microcontroller and embed	lded			
microcontrollers.						
• Familiarize the basic architectu	are of 8051 micro controller	r.				
• Program 8051microprocessor	using Assembly Level Lang	guage and C.				
• Understand the interrupt system	n of 8051 and the use of int	terrupts.				
• Understand the operation and u	use of inbuilt Timers/Count	ers and the Serial port of 80	51.			
• Interface 8051 to external men						
	Module-1		08 hrs			
8051 Microcontroller: Micro	oprocessor Vs Microcon	ntroller, Embedded Syst	ems, Embedded			
Microcontrollers, 8051 Architec	•	•	,			
organization. External Memory	• •	•				
Text2 : Chapter 1 section 1.1 to						
-						
RBT Level:	L1, L2, L3	wer i ollit i resentation,				
	Module-2		08 hrs			
8051 Instruction Set: Addressin		tructions Arithmatic instruc				
instructions, Bit manipulation in	-		-			
loops) to use these instructions.	istituetions. Simple Assembl	y language program examp	ies (without			
1 /	antar 7 abortar 8					
Text2 : Chapter 5 , chapter 6, ch		wan Daint Dragantation				
Teaching Learning Method:	Chalk and talk method, Por	wer Point Presentation				
RBT Level:	L1, L2, L3 Module-3		001			
	08 hrs					
8051 Jump and Call instruction	-					
instructions. Assembly language		• •				
8051 Programming in C: Data T	ypes and Time delay in 805	of C, I/O programming in 80	051 C, Logical			
Operations in C.						
Text2 : chapter 8 section 8.1 to	1					
Teaching Learning Method:	Chalk and talk method, Por	wer Point Presentation				
RBT Level:	L1, L2, L3					
	Module-4		08 hrs			
8051 Timers and Serial Port 805	1 Timers and Counters - Op	peration and Assembly langu	lage programming			
to generate a pulse using Mode-	1 and a square wave using 1	Mode- 2 on a port pin.				
8051 Serial Communication- Ba	sics of Serial Data Commu	nication, RS-232 standard,	9 pin RS232			
signals, Simple Serial Port progr	ramming in Assembly and O	C to transmit a message and	to receive data			

Feaching Learning Method:RBT Level:8051 Interrupts and Interfacinggenerate an external interruptport pin using a timer interrupt8051 Assembly and C languageFext 1: Chapter 11 section 11.1	L1, L2, Mg Applica	Iodule-5	-	Powe	r Point	Presen	tation,								
3051 Interrupts and Interfacing generate an external interrupt port pin using a timer interrupt 3051 Assembly and C language	N g Applica	Iodule-5													
generate an external interrupt port pin using a timer interrupt 8051 Assembly and C language	N g Applica	Iodule-5				L1, L2, L3									
generate an external interrupt port pin using a timer interrupt 8051 Assembly and C language			,						08	hrs					
generate an external interrupt port pin using a timer interrupt 8051 Assembly and C language		tions.80	51 Inte	rrupts.	8051	Assemb	ly lang	uage pi	rogrami	ning to					
bort pin using a timer interrupt 8051 Assembly and C language				-					-	-					
8051 Assembly and C language	-		-	-	-	-		-							
					, DI	с, цер	und St	opperi	notor u	ia titeli					
lext I: Chapter II section II.		01 0		•	2.1 ± 0.1	2.2 ah	ontor 1	antin	n 12 1						
1 17		. Chapte			5.1 10 1	5.2, ch	apter 12	2 sectio	11 12.1,						
chapter 17 section 17.2	~1 11	1 11					•								
Teaching Learning Method: Chalk and talk method, Power Point Presentation DDTL L1 L2 L2															
RBT Level: L1, L2, L3															
Course outcomes:															
At the end of the course, the	student v	vill be al	ole to:												
CO1. Explain the difference									cture o	f 805					
Microcontroller, Interfacing of			•	·				•							
CO2. Develop 8051 Assembly	1	0	0												
CO3. Develop 8051 Assembly				genera	te timiı	ngs and	wavefo	orm usir	1g 8051	timers					
o send & receive serial data us	0	-													
CO4. Develop 8051 Assembly	-		-	-	-			051 I/C) port pi	n usin					
nterrupt and C Programme to					-	serial p	ort.								
CO5. Interface various periphe		es to 805	51 using	g I/O p	orts.										
Suggested Learning Resource	es:														
Fext Books:			11												
I: Kenneth J. Ayala, "The	8051 Mi	crocontr	oller",	Kenne	th J Ay	vala, 3ro	d Editic	on, Tho	mson/C	engag					
Learning.	· · ·	C 11				.	D 14	T 7• 1		005					
2: Muhammad Ali Mazidi										\$ 805					
Microcontroller and Embedded	Systems	– using	assemt	oly and	I C", PI	HI, 200	6 / Pear	son, 20	06.						
Reference Books:	D 1 E.	.1 1 1 . 1	0			D-4-1	M		2014 1						
1. "The 8051 Micro controller	Based En	nbeaaea	System	IS [*] , M	anish K	Patel,	McGra	w Hill,	2014, 1	SBN:					
978-93-329-0125-4.	Due o		Tutan		1 C	at a una D			mal Da						
2. "Microcontrollers: Architect	ure, Prog	ramming	g, Interi	acing	and Sys	stem D	esign,	кај ка	mai, Pe	arson					
Education, 2005. Web Links: https://swayam.go	win/nd1	noo20	ng 25												
Activity Based Learning (Sug				oo)/ D.	ontinal	Dagad	loorni	na							
l: Programming 8051 using As					actical	Daseu	learnn	ng							
rogramming 0001 using A	seniory d		5 ans.												
		CO-]	PO Ma	pping											
P01 P02 P03 P04	P05 P	D6 P07	P08	P09	P010	P011	P012	PS01	PSO2	PSO3					
CO1 3 3 CO2 2 2 2				1					2						
CO2 3 3 2 CO3 3 3 2	1 1			1					22						
CO3 3 3 2 CO4 3 3 2	1			1					2						
CO5 3 3 2	1			1					2						

IV Semester

	PC	WER ELECTI	RONICS		
Course Code:	22	2ECT405B		CIE Marks:	50
Teaching Hours/Week (L:T:P	:S): 3:	0:0:0		SEE Marks:	50
Total Hours of Pedagogy:	4			Total Marks:	100
Credits:	0.	3		Exam Hours:	03
Course objectives:					
 To get an overview of difference To understand the operation, To Understand the fundament 	characteri tal princip	stics of thyristor les of basic pow	s. er electron	ic converters.	
4. To describe the need and fun			power elec	ctronics converters	
		odule-1			08 hrs
INTRODUCTION: Application characteristics, types of power of THYRISTORS: Introduction,	electronic	circuits, peripher	ral effects		
and dv/dt protection.			tor model,	turn-on and turn of	n methods, ul/at
Teaching Learning Method:	Chalk an	d talk method, P	ower Point	Presentation,	
RBT Level:	L1, L2,L	3			
	M	odule-2			08 hrs
commutation, impulse commut Teaching Learning Method: RBT Level:	-	d talk method, P			commutation.
		odule-3			08 hrs
AC VOLTAGE CONTROLL			le ef ON (
bidirectional controllers with re CONTROLLED RECTIFIEN phase semi converters, full conv	esistive loa RS: Introdu	ads. uction, principle	of phase co	-	
-		d talk method, P		Duccontation	
Teaching Learning Method: RBT Level:	L1,L2,L3	· · · · · · · · · · · · · · · · · · ·	ower Politi	Presentation,	
	M	odule-4			08 hrs
DC CHOPPERS: Introduction	, principle	of step-down op	peration, st	ep-down chopper v	vith RL loads,
Principle of step-up operation, s	step-up ch	opper with Resis	stive load, p	performance param	eters, Chopper
classification (Class A to Class	E).				
Teaching Learning Method: RBT Level:	Chalk an L1,L2,L3	d talk method, P	ower Point	Presentation,	
		odule-5			08 hrs
INVERTERS: Introduction, pr			rmance nat	ameters single nh	
inverters, Three phase inverters principles of switched mode po	, voltage c	control of single			

Teaching Learning Method:	Chalk and talk method, Power Point Presentation,
RBT Level:	L1,L2,L3
Course outcomes:	
At the end of the course the st	tudent will be able to:
CO1. To give an overview of	applications power electronics, different types of power semiconductor
devices, explain the constructio	n, working and characteristics of SCR
CO2. To analyse different com	mutation techniques of SCR
CO3. To explain the analysis	techniques, performance parameters and characteristics of controlled
rectifiers and Voltage controller	rs
CO4. To explain the analysis	techniques, performance parameters and characteristics of DC-to-DC

1 D

n

C1 11

1 / 11

CO4. To explain the analysis techniques, performance parameters and characteristics of DC-to-DC converters

CO5. To explain the analysis techniques, performance parameters and characteristics of DC to AC converters

Suggested Learning Resources:

Text Books:

T

1: Ned Mohan, Tore M. Undeland, William P Robbins, "Power Electronics: Converters, Applications, and Design", John Wiley and Sons Inc.,, New York, 2003.

2: Rashid M.H., "Power Electronics Circuits, Devices and Applications ", Prentice Hall, India, New Delhi, 2004.

3: Joseph Vithayathil, e, "Power Electronics, Principles and Applications", Tata McGraw-Hill Edition, 2010.

Reference Books:

1: Singh M.D., Khanchandani K B, "Power Electronics", Tata McGraw Hill, 2nd Edition, New Delhi, 2007.

2: Dr.P.S.Bimbra., "Power Electronics", Khanna Publications, 3rd Edition, 2003.

Activity Based Learning (Suggested Activities in Class)/ Practical Based learning

Activity 1:

Activity 2:

Activity 3:

CO-PO Mapping

	P01	P02	PO3	P04	P05	P06	P07	P08	P09	P010	P011	P012	PS01	PSO2	PSO3
CO1	2	2											2	3	
CO2	3	3											2	3	
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IV Semester

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IV Semester

functions.

		C++ Basics							
Course Co	de	22ECL406A	CIE Marks	50					
Teaching l	Hours/Week (L: T:P: S)	0:0:2:0	SEE Marks	50					
Credits		01	Exam Hours	03					
Course ob	iectives:	01							
-	-	mming concepts, and	apply them in solving problem	ms.					
	ite, debug and run simple C	• •							
	• •		heritance, polymorphism and	function					
overloa	ding.								
4. Introdu	ce the concepts of exceptio	n handling and multit	hreading.						
Sl. No		Exper							
1		-	est & second largest of thre	e numbers using					
	inline functions MAX &								
2	Write a C++ program to calculate the volume of different geometric shapes li								
2	cylinder and sphere using								
3	Define a STUDENT class with USN, Name & Marks in 3 tests of a subject. Declare an								
	array of 10 STUDENT objects. Using appropriate functions, find the average of the two better marks for each student. Print the USN, Name & the average marks of all the students.								
4	Write a C++ program to create class called MATRIX using two-dimensional array of								
•			th checks the compatibility of						
			on and subtraction by overlo						
			overloading the operator <<	U					
	then $m3 = m1 + m2$ and		• •	· (
5			creating a base class FAT	HER with data					
	-		k Balance and creating a der						
	which inherits: Surname	e & Bank Balance f	eature from base class but p	provides its own					
	feature: First Name &	DOB. Create & in	itialize F1 & S1 objects w	with appropriate					
	constructors & display the	he FATHER & SON	details.						
6	10		ne FATHER & SON that h						
_			of a family using Friend funct						
7	10	to accept the student detail such as name & 3 different marks by							
		•	age of marks using display()						
0		<u> </u>	ks using the method mark_av						
8		-	ction (Polymorphism) by crea	-					
	1		vo classes rectangle & trian	-					
9			the area of rectangle & triang						
	Design, develop and execute a program in C++ based on the following requirements: Ar EMPLOYEE class containing data members & members functions: i) Data members								
	employee number (an integer), Employee_ Name (a string of characters), Basic_ Salary (in								
	integer), All_ Allowand	• • •		er). (ii) Member					
		e de la companya de la	calculate Net_Salary & to p						
			3% of Basic, Income Tax (IT						
	salary (=basic_ Salary_A		``````````````````````````````````````	2					
10			ss related through multipl	e inheritance &					
	demonstrate the use of di	fferent access specifi	ed by means of members vari	ables & member					
	functions								

11		Write	e a C+	+ pro	gram	to cre	ate thr	ree ob	jects f	for a	class n	amed o	count o	bject w	rith data
		mem	members such as roll_no & Name. Create a members function set_data () for setting												
		the d	the data values & display () member function to display which object has invoked it using												
		"this'	"this" pointer.												
12	2	Write	Write a C++ program to implement exception handling with minimum 5 exceptions												
		classe	classes including two built in exceptions.												
Sugges	ted Le	arning	Resou	rces:											
1.	Objec	torien	ted pro	gramm	ing in T	URBO (C++, Rol	bert La	fore, Ga	lgotia	Publicat	ions, 200	02		
2.	The C	omplet	e Refer	ence C-	++, Herł	oert Scł	nildt, 4 ^{ti}	^h Editio	on, Tata	McGra	aw Hill, 2	2003.			
3.	Objec	t Orien	ted Pro	gramm	ing wit	h C++, I	E Balagı	ıruswa	my, 4 th	Editio	n, Tata M	IcGraw I	Hill, 2006	5 .	
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Dr. AMBEDKAR INSTITUTE OF TECHNOLOGY, BEGALURU -

560056.

(An Autonomous Institution Affiliated to Visvesvaraya Technological University, Belgaum)

Department of Electronics & Communication Engineering

Ref. No: AIT /EC /BOS / 467 /2023-24

Date: 12-08-2023

To Dean (Academic) Dr Ambedkar Institute of Technology Bengaluru-56

Sir,

Sub: Regarding the details of the BOS meeting held on 12-08-2023

The External BOS 2023-24 meeting was held in blended mode in the department of the Electronics and communication Engineering and through Google meet link: https://meet.google.com/iun-vhbc-tfs on Saturday, 12-08-2023 10:30 am.

The BOS committee has approved the following:

- 1. NEP based Scheme and I & II semester syllabus of UG Courses of the 2023 Batch Students.
- 2. NEP based Scheme and III & IV semester syllabus of UG Courses of the 2022 Batch Students.
- 3. NEP Based Scheme and V & VI semester Syllabus of UG Courses of the 2021 Batch Students.
- 4. VII & VIII semester Syllabus of UG Courses of the 2020 Batch Students.
- 5. Skill Lab for 2023 batch students.
- 6. Scheme and Syllabus of I and II-year PG course.
- 7. The List of BOE members.
- 8. The list of Valuers / Examiners.

Thanking you

Taldlipa V Mand

CHAIRMAN BOS Dept. of ECE

Dept. of Electronics and Communication Engg. Dr. Ambedkar Institute of Technology Bengaluru - 560056

Enclosures:

- 1. List of Members of BOS.
- 2. Curriculum Design -UG
- 3. Minutes of the BOS Meeting.
- 4. Scheme & Syllabus of I/II Semester Basic Electronics and Communication Engineering for the academic year 2023-24.
- 5. Scheme & Syllabus of 3rd and 4th Semesters for the academic year 2023-24.
- 6. Scheme & Syllabus of 5th and 6th Semesters for the academic year 2023-24.
- 7. Scheme & Syllabus of 7th and 8th Semesters for the academic year 2023-24.
- 8. List of BOE Members.
- 9. List of valuers / Examiners.



Dr. AMBEDKAR INSTITUTE OF TECHNOLOGY, BEGALURU -560056. (An Autonomous Institution Affiliated to Visvesvaraya Technological University, Belgaum)

Department of Electronics & Communication Engineering

Members of BOS:

SI No.	CATEGORY	Nomination of the Committee	Name of the Person with Designation			
1	Head of the Department	Chairperson	Dr. Mahalinga V Mandi, Dean (P&D), Professor & Head, Department of ECE, Dr. AIT, Bengaluru-56			
		Member 1.	Dr. Umadevi H. Professor, Department of ECE, Dr. AIT, Bengaluru-56			
		Member 2. Dr. Ramesh S, Dean (Exam), I Department of Bengaluru-56				
	Faculty Members at	Smt. Sudha B S. Associate Professor, Department of ECE, Dr. AIT, Bengaluru-56				
		Member 4.	Dr. Shivaputra Assistant Professor Department of ECE, Dr. AIT, Bengaluru-56			
2	Different Levels Bearing Different Specializations	Member 5.	Dr. Meenakshi.L.R. Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56			
		Member 6.	Mr. Mohan Kumar V Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56			
		Member 7.	Dr. Jambunath S Baligar Associate Professor Department of ECE, Dr. AIT, Bengaluru-56			
		Member 8.	Dr. Chetan. S Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56			
3	Subject Experts from outside the College Nominated by Academic Council	Member 1.	Dr. Devendra Jalihal Professor, EEE department IIT Madras, Chennai-600 036			



Dr. AMBEDKAR INSTITUTE OF TECHNOLOGY, BEGALURU -

560056.

(An Autonomous Institution Affiliated to Visvesvaraya Technological University, Belgaum)

Department of Electronics & Communication Engineering

		Member 2.	Prof. Santanu Mahapatra Professor, Department of Electronic Systems Engineering, Indian Institute of Science Bangalore, Bengaluru- 560012
		Member 3.	Dr. Mandeep Singh Professor, Department of ECE, NITK, Surathkal
		Member 4.	Prof. P.Nagaraju Associate Professor, Dept. of TCE, RVCE, Bengaluru-560 059
4	Expert from outside College, Nominated by Vice Chancellor (VTU)	VTU Nominee	Dr. Manajanaik N Professor, Department of ECE, UBDT, Davangere, Karnataka
	Representative from Industry /Corporate Sector/Allied area related to Placement	Member 1.	Mr. Kubendra.K Senior Design Engineer VLSI Group, Samsung India,Outer ring Road, Near Marathahalli, Bengaluru
	Nominated by Academic council	Member 2.	Mr. Somshekar H Mobileum India Pvt ltd., Director of Engineering.
5		Member 3.	Mr. Sampath Kumar Srinivas Mitel, Senior Staff Software Engineer Manyata Tech Park, Bangalore
6	Post Graduate Meritorious alumnus nominated by Principal	Member	Mr. Premkumar M N Senior Manager, Intel, India Bengaluru

Davalipa V Mande

CHAIRMAN **BOS Dept. of ECE** HOD Dept. of Electronics and Communication Engg., Dr. Ambedkar Institute of Technology Bengaluru - 560056



MINUTES OF THE MEETING OF THE BOARD OF STUDIES 2023-24

DATED: Saturday, 12th August 2023

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(An Autonomous Institution Affiliated to Visvesvaraya Technological University, Belgaum)

Department of Electronics & Communication Engineering

BOS Meeting Notice

Sub: Board of Studies Meeting is convened on 12-08-2023

With reference to the above subject, External Board of Studies Meeting of the department is convened on Saturday, the 12th August 2023 at 10:30 a.m. in Department of ECE for finalizing the scheme and syllabus of UG in B.E. (E & C) and PG, M.Tech in VLSI Design and Embedded Systems for the academic year 2023-24 with the following agenda.

Agenda:

- Approval of the NEP Scheme and Syllabus of 1st to 8th Semesters B.E (E &C) for the Batch-2023
- Approval of the NEP Scheme and Syllabus of 3rd to 8th Semester B.E(E & C) for the Batch -2022
- Approval of the NEP Scheme and Syllabus of 5th to 8th Semester B.E(E & C) for the Batch-2021
- Approval of the Scheme and Syllabus of 7th to 8th Semester B.E(E & C) for the Batch-2020
- 5. Approval of Basic IoT Skill Lab for the Batch-2023 students.
- Approval of the Scheme and Syllabus for the 1st and 2nd Semester PG for the Batch-2023
- 7. Approval of the Scheme and Syllabus for the 3rd and 4th Semester PG for the Batch-2022.
- 8. Approval of the courses for the Major, Minor Degree
- 9. Approval of List of Examiners



Minutes of Board of Studies (BOS) Meeting:

The Meeting of Board of Studies (BOS) for Department of Electronics and Communication Engineering was held on 12-08-2023 at 10:30 a.m. under the Chairmanship of the Dr. Mahalinga V. Mandi, Dean (P&D), Professor and Head, Department of Electronics and Communication Engineering in the department of Electronics and Communication engineering and through Google meet link: https://meet.google.com/iun-vhbc-tfs.

At the very outset, the Chairman welcomed all the Internal and External members of BOS to the meeting and gave a preliminary presentation on the agenda items with reference to the scheme and syllabus of UG and PG for the academic year 2023-24

The chairman along with BOS coordinators gave a detailed presentation of the courses to be offered to the students in both Core and Elective subjects in semester wise at the Under Graduate level and Post Graduate level, also briefed the members about the Curriculum Design of the Department for the UG and PG Courses.

PROCEEDINGS/RESOLUTIONS:

The following are the Suggestions of the members of BOS with reference to the presentations:

I and II semester for 2023 batch:

- Subject Expert Devendra Jalihal Suggested to reduce the syllabus for "Basic electronics" (Module 1) for ECE
 Sol. Internal BOS members clarified that most of the topics will be dealt up to Remembering & Understand level (L1, L2)
- Subject Expert Mandeep Singh suggested to include recent edition text books for the course Introduction to Electronics Engineering (22EST104C/204C).
 Sol. Recent edition text books prescribed for subject Introduction to Electronics Engineering (22EST104C/204C).

III and IV Semesters for 2022 batch:

 Subject Expert Devendra Jalihal suggested to rearrange the contents of the topic Fourier Transforms in the subject "Signals and Systems".
 Sal Table Equation Transformed as a statement of the subject "Signals and Systems".

Sol. Topic Fourier Transforms in the subject "Signals and Systems" is rearranged as per the suggestions.



 Subject Expert Dr. Nagaraju P remarked regarding the IPCC subject Analog Electronic Circuits (21ECT303) that JFET experiment was added in practical component while only concepts of MOSFET were dealt in theory.

Sol. JFET experiments in practical component is replaced by MOSFET experiments.

- Subject Expert Dr. Nagaraju P suggested to reduce the contents of 7th and 8th experiments in Analog and Digital Electronics Lab (22ECL305).
 Sol. Redundant experiments are removed as per suggestions.
- Subject Expert Dr. Nagaraju P suggested to include Proportional controller concept in module 3 in the IPCC subject Modern Control Systems as these concepts were included in practical component.

Sol. Proportional Controller Concepts included in module 3.

V and VI Semesters for 2021 batch:

- Industry Expert Sampath Kumar Srinivas seek clarification regarding the duration for mini project.
- Industry Expert Sampath Kumar Srinivas suggested to include IPV6 concept in Computer Communication Networks (21ECT503).
 Sol. IPV6 concept included as per suggestion.
- Subject Expert Dr. Nagaraju P suggested to include recent edition books for the subject Microwave and Antenna.

Sol. Prescribed Textbooks updated to recent editions.

- Industry Expert Kubendra suggested to include RISC V concepts in Microprocessor and Microcontroller subject.
 Sol. RISCV concepts included as Module 4 and Module 5 in Microprocessor and Microcontroller subject.
- Subject Expert Dr. Nagaraju P suggested to include Embedded C experiments instead of Assembly Programs in the subject CO & ARM Processor.
 Sol. Assembly Programs replaced with embedded C programs.
- Subject Expert Dr. Nagaraju P suggested to update prescribed text books for the subject ANN Sol. Prescribed text books updated to recent editions.
- Discussed about the Scheme and syllabus of 7th and 8th semester for 2020 batch
- No comments on final year subjects, so retained same syllabus.
- Discussed about the Scheme and syllabus of 1st and 2nd year PG program.
- Subject Expert Devendra Jalihal remarked that the number of electives are more. Sol. PG coordinator clarified that scheme and syllabus is framed as per VTU guidelines.
- Subject Expert Dr. Nagaraju P suggested to include recent edition text books.
 Sol. Recent edition text books are prescribed.





Dr. AMBEDKAR INSTITUTE OF TECHNOLOGY, BEGALURU – 560056. (An Autonomous Institution Affiliated to Visvesvaraya Technological University, Belgaum)

Department of Electronics & Communication Engineering

• The meeting was ended with vote of thanks by Dr. Mahalinga V. Mandi, Dean (P&D), Professor and Head, Department of ECE.

Finally, the BOS members approved the following after incorporating the suggested modifications

- Approved the Curriculum Design for the semesters I to VIII of UG Course for the students of the Batch 2023
- Approved the NEP Based Syllabus of Basic Electronics and Communication Engineering for the semesters I/II of UG Course for the academic year 2023-24.
- Approved the NEP Based Scheme and syllabus for semesters III and IV of UG Course for the academic year 2023-24.
- Approved the NEP Based Scheme and syllabus for semesters V and VI of UG Course for the academic year 2023-24.
- Approved the Scheme and syllabus for semesters VII and VIII of UG Course for the academic year 2023-24.
- Approved Basic IoT Skill Lab for 2023 batch students.
- Approved I and II-year scheme and syllabus of PG Course for academic year 2023-24.
- > Approved the courses for the Major, Minor Degree
- > Approved the List of BOE members.
- > Approved the list of Valuers / Examiners.

CHAIRMAN **BOS Dept. of ECE**

BOS Coordinators

- 1. Prof. B. S. Sudha
- 2. Mr. Anand H D

Signatures Sudha , A. is (2) (202) (2) (202)



List of BOE Members:

SL. NO.	NAME AND ADDRESS
1.	Dr. Mahalinga V. Mandi, Dean (P & D), Professor and Head, Department of ECE
Exte	rnal BOE members:
1.	Dr. Dinesh P., Professor and Dean, Department of ECE, DSCE, Bengaluru
2.	Prof. Nagraju P, Associate Professor, Department of TCE, RVCE, Bengaluru
3.	Dr. Rajeshwari Hegade, Professor and Head, Department of TCE, BMSCE, Bengaluru-19
4.	Dr. Revanna, Associate Professor, Department of ECE, Govt. Engineering College, Ramanagara
Inter	mal BOE Members:
1.	Dr. Umadevi H., Professor
2.	Smt. Sudha B. S., Associate Professor
3.	Dr. Shivaputra, Assistant Professor
4.	Smt. Meenakshi L. Rathod, Assistant Professor
5.	Mr. Mohankumar V., Assistant Professor
6.	Smt. Girija S., Assistant Professor

Talipar nand. CHAIRMAN

BOHODPt. of ECE Dept. of Electronics and Communication Engg., Dr. Ambedkar Institute of Technology Bengaluru - 560056



Dr. AMBEDKAR INSTITUTE OF TECHNOLOGY

(An Autonomous Institution Affiliated to Visvesvaraya Technological University, Belgaum)

Department of Electronics & Communication Engineering

12-08-2023

Attendance list:

Sl. No	Position	Name	Signature with date
1.	Chairman	Dr. Mahalinga V. Mandi Professor and Head Department of ECE, Dr. AIT, Bengaluru-56	navalipav nand. 12/8/23
2.	VTU Nomince	Dr. Manajanaik N Professor, Department of ECE, UBDT, Davangere, Karnataka	ABSENT
3.	External Subject Experts	1. Dr. Devendra Jalihal Professor, EEE department IIT Madras, Chennai-600 036	Pousert Online.
		2. Dr. Santanu Mahapatra Professor, Department of Electronic Systems Engineering, Indian Institute of Science Bangalore,560012	ABSENT
		3. Dr. Mandeep Singh Professor, Department of ECE, NITK, Surathkal	Paesent Online
		4. Dr. P. Nagaraju Associate Professor, Dept. of TCE, RVCE, Bengaluru-560 059	P. Wyt. 19hollors
4.	Industry Expert	1. Mr. Kubendra K Senior Design Engineer VLSI Group, Samsung India, Outer ring Road, Near Marathahalli, Bengaluru	Present Online.
		2. Mr. Somshekar H Mobileum India Pvt ltd., Director of Engineering.	ABSENT
2		3. Mr. Sampath Kumar Srinivas Mitel, Senior Staff Software Engineer Manyata Tech Park, Bangalore	5: Geph 1- 12/8/2023

5.	Alumni with PG Degree		Premkumar M N ior Manager, Intel, India Bengaluru	ADSENT .
6.	Internal Members	1.	Dr. Umadevi H. Professor, Department of ECE, Dr.AIT,	Hlund
			Bengaluru-56	12/8/2
		2.	Dr. Ramesh S. Professor, Dean (E) Department of ECE, Dr. AIT, Bengaluru-56	Qw12-8-27
		3.	Smt. Sudha B. S. Associate Professor, Department of ECE, Dr. AIT, Bengaluru-56	5-2010-8
		4.	Dr. Shivaputra Assistant Professor Department of ECE, Dr. AIT, Bengaluru-56	on Leave
		5.	Dr. Meenakshi L. R. Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56	le 12/08/20
		6.	Mr. Mohan Kumar V. Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56	Huen 12/08/20
		7.	Dr. Jambunath S. Baligar Associate Professor Department of ECE, Dr. AIT, Bengaluru-56	Khr 12/0/23
		8.	Dr. Chetan S. Assistant Professor, Department of ECE, Dr. AIT, Bengaluru-56	alitan 212/81
7.	Student Representatives:	1.	NOgesh.N.V IDAZIECIZO	Vogeshu
		2.	Yalavathi.v IDA21 ECI68	Jalewathi N
		3.	Bhulini RR IDADDEC4D6	Jalewathi N Shuti: PR
		4.	LIKHITHA . B IDA20 EC066	Elitea
		5.	Divyashree. K DA20EC 041	Dinga

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6. Jagunthé. S IDA20EC053 fagit	iù
7. Studiu. Hosamani IDA22LV303	
8. Rachmi. R IDA22LVSOD	

Marahipa V. Nord Signature HOD, Dept. of ECE **BOS Chairman** HOD Dept. of Electronics and Communication En-Dr. Ambedkar Institute of Technology

Bengaluru - 560056

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